

## V850E2/ML4

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### Updating Program Code by Using Flash Self Programming with Asynchronous Serial Interface J (UARTJ)

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#### Abstract

This document describes an example to update program code by reprogramming on-chip flash memory in V850E2/ML4 using flash self programming with serial communication.

The features of the example to update program code in this Application note are described below.

- Reprograms a program code in the flash memory area using update program file with Intel expanded hex format received through serial communication.
- For the procedure in case of reprogram failure such as reprogram processing is aborted without intention, an error control register by checksum is included.

#### Products

V850E2/ML4

When using this application note with other Renesas MCUs, careful evaluation is recommended after making modifications to comply with the alternate MCU.

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### 1. Specifications

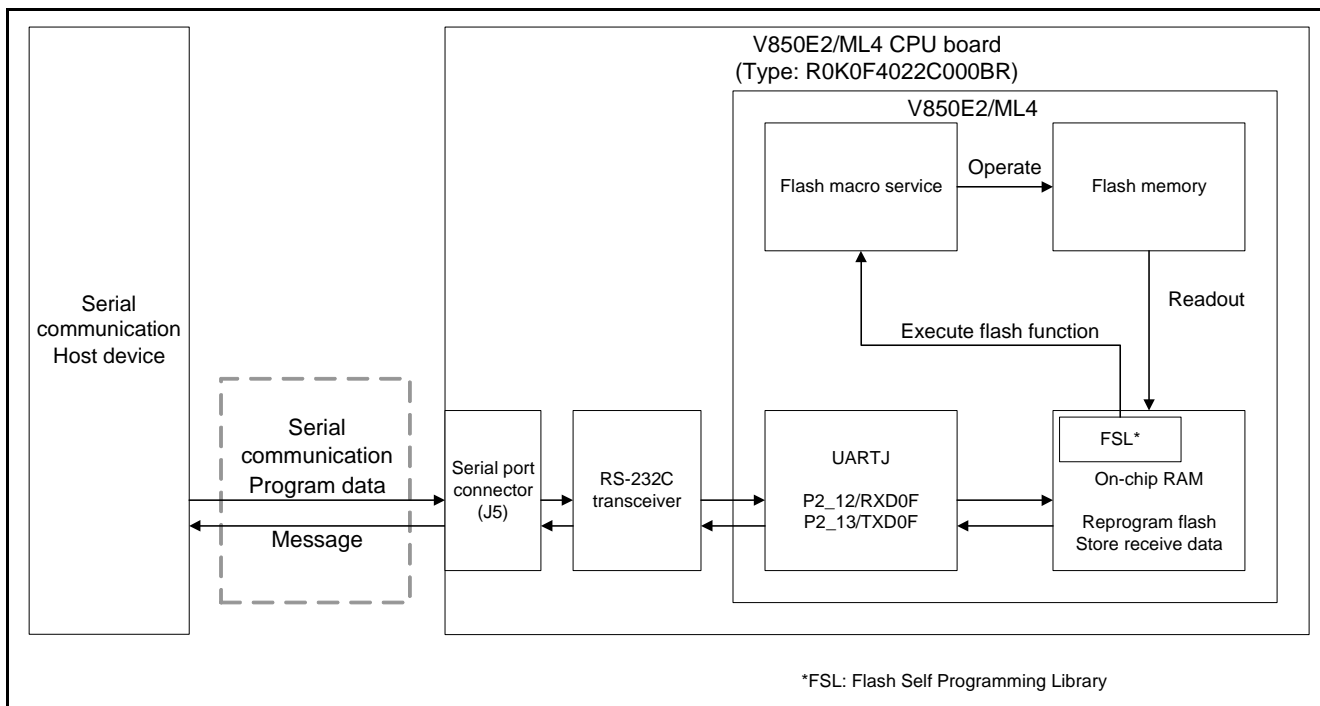
In this Application note, a program code update is performed by reprogramming on-chip flash memory using flash self programming.

Serial communication with an arbitrary device enables to receive a program file data for update with Intel expanded hex format type and reprogram a program code in the on-chip flash memory area.

Table 1.1 lists the Peripheral Functions and Their Applications and Figure 1.1 shows the System Configuration.

**Table 1.1 Peripheral Functions and Their Applications**

Peripheral Function	Application
Flash memory (on-chip flash memory)	Program storage area
Flash macro service	Reprogramming flash memory
Asynchronous serial interface J (UARTJ)	Reprogramming data/Message communication



**Figure 1.1 System Configuration**

## 2. Operation Confirmation Conditions

The sample code accompanying this application note has been run and confirmed under the conditions below.

**Table 2.1 Operation Confirmation Conditions**

Item	Contents
MCU used	V850E2/ML4
Operating frequency	Internal system clock ( $f_{CLK}$ ) : 200MHz P bus clock ( $f_{PCLK}$ ) : 66.667MHz
Operating voltage	Positive power supply for external pins ( $E_{V_{DD}}$ ) : 3.3V Positive power supply for internal units ( $I_{V_{DD}}$ ) : 1.2V
Integrated development environment	Renesas Electronics Corporation CubeSuite+ Ver.1.02.01
C compiler	Renesas Electronics Corporation CX compiler package Ver.1.21 Compile option -Cf4022 -oDefaultBuild\v850e2ml4_flash_update_uartj.lmf -Xobj_path=DefaultBuild -g -Xpro_epi_runtime=off -IC:\Workspace\v850e2ml4_flash_update_uartj\inc -IC:\Workspace\v850e2ml4_flash_update_uartj\FSL -Xdef_var -Xfar_jump=v850e2ml4_flash_update_uartj.fjp -Xlink_directive=v850e2ml4_flash_update_uartj.dir -Xstartup=DefaultBuild\cstart.obj +Xide -Xmap=DefaultBuild\v850e2ml4_flash_update_uartj.map -IFSL_T05_REC_R32 -LC:\Workspace\v850e2ml4_flash_update_uartj\FSL\lib -Xrompsec_text=FSL_CODE.text -Xrompsec_text=FSL_CODE_ROMRAM.text -Xrompsec_text=FSL_CODE_RAM.text -Xrompsec_text=FSL_CODE_RAM_USRINT.text -Xrompsec_text=FSL_CODE_RAM_USR.text -Xrompsec_text=FSL_CODE_RAM_EX_PROT.text -Xrompsec_text=INTP1RAM.text -Xrompsec_text=INTTAUA0I0RAM.text -Xrompsec_text=INTUARTJ0IRRAM.text -Xhex=DefaultBuild\v850e2ml4_flash_update_uartj.hex
Operating mode	Normal operating mode (Will be changed to flash memory programming mode at the time of reprogram)
Sample code version	1.00
Board used	R0K0F4022C000BR
Device used	Serial communication host device

### 3. Reference Application Notes

For additional information associated with this document, refer to the following application notes.

- V850 Microcontroller Flash Self Programming Library Type05 (R01AN0661EJ)

### 4. Peripheral Functions

This chapter provides supplementary information on the flash self programming library which is required to reprogram the flash memory using the software operated on the V850E2/ML4. Refer to the "V850E2/ML4 User's Manual: Hardware" and the "V850 Microcontroller Flash Self Programming Library Type05" for basic information.

#### 4.1 Terms for Flash Self Programming

The terms for flash self programming used in this Application note are described as follows.

- Flash macro service  
This refers to functions for manipulating the flash memory in devices.
- Flash environment  
This refers to the state in which the code flash can be operated by using the flash macro service. There are special restrictions different from execution of normal programs. A transition to other environment cannot occur unless the flash environment is ended.
- Flash function  
This refers to the individual functions comprising the self-library. They can be used with the C language.
- Internal verification  
This refers to the action of internally checking the signal level and verifying that the signal can be read normally following write to flash memory.

## 4.2 Notes for Flash Self Programming

The V850E2/ML4 has the flash macro service which operates the flash memory. This sample program describes how to reprogram a program code using the flash self programming library (FSL) which enables to use the flash macro service with C language. The following notes are provided to use this library.

- The program allocation in RAM executed during the flash environment (including runtime library)
  - Setting for a section to allocate the program in RAM  
Creation and setting for the link directive file is required to set a section. Refer to "4.2.1 Setting for Link Directive File" for more details.
  - Setting for non-use or allocation in RAM for the functional prologue/epilogue runtime library  
This sample program runs the non-use setting of the prologue/epilogue runtime library. Refer to "4.2.2 Setting for Non-use of Prologue/Epilogue Library" for more details.
  - Setting for the exception handler address switching function when using interrupts  
The setting for the exception handler address switching function is executed by the software. Refer to "6.7.3 Switching Processing of Exception Handler Address" for more details.
  - Initialization of the program area in the RAM allocation destination  
When allocating a program to RAM on the V850E2/ML4, the 16-byte boundary area (H'xxxx\_xxx0 to H'xxxx\_xxxF) including the program area in the allocation destination is required to be initialized (cleared to zero). In this sample program, the initialization is executed during the startup routine. Refer to "4.2.5 Setting for Startup Routine" for its change, and "6.7.1 Startup Routine Processing" for its details.
  - Setting for ROMization of the section to expand the program in RAM  
Regarding to the setting for ROMization on the CubeSuite+, refer to "4.2.3 Setting for ROMization of Section in RAM".
- The execution of the flash functions are disabled in the interrupt handler
- The far jump specification for the CX compiler when calling function allocated to the address separated more than 2 MB  
In this sample program, the far jump option is specified to the function allocated in RAM which is called from the flash memory. Refer to "4.2.4 Setting for Far Jump Function" for more details.
- Saving, setting and restoring the gp register and the ep register when accessing to the global variables with C language in the interrupt handler  
The above mentioned operations might be required when accessing to the data section in the interrupt handler. Refer to "4.2.6 Precautions for Interrupts Generated During Use of FSL" for more details.

In regard to the function specification and the system configuration of the FSL, refer to the reference application note, "V850 Microcontroller Flash Self Programming Library Type05".

In regard to section specification to the CX compiler, allocation address setting, ROMization, and far jump option specification on the CubeSuite+, refer to "CubeSuite+ V1.03.00 Integrated Development Environment User's manual: Build (CX compiler)".

In regard to switching the exception handler address, refer to "V850E2 User's Manual: Architecture".

### 4.2.1 Setting for Link Directive File

The link directive file creation and the CubeSuite+ setting are required to change the section assignment. When creating the link directive file using text editor without the CubeSuite+ menu, the Cube Suite+ setting is required. Drag the link directive file from explore, and drop it in blank area, the bottom part of the Project Tree. In the CubeSuite+, the file which has extension of "dir" or "dr" is considered as the link directive file. Select "CX (Build Tool)" under the Project Tree, and click "Link Options" tab in the Property. Open "Input File" to check "Using link directive file". Refer to "CubeSuite+ V1.03.00 Integrated Development Environment User's manual: Coding (CX compiler)" for more details.

When creating the link directive file, in this sample program, the reprogram area section (MasterPRG.text), the spare area section (SparePRG.text), and the FSL area (FSL.CONST) should be created in the flash memory other than the default area. In addition, the FSL use area and user program area sections (FSL\_DATA.bss, FSL\_CODE.text, FSL\_CODE\_ROMRAM.text, FSL\_CODE\_RAM.text, FSL\_CODE\_RAM\_USRINT.text, FSL\_CODE\_RAM\_USR.text, and FSL\_CODE\_RAM\_EX\_PROT.text), and exception handler address sections (INTP1RAM.text, INTTAUA0I0RAM.text, INTFCNOIERRRAM.text, and INTFCNOIRECRAM.text) should be created in RAM.

In this sample program, the start address of the MasterPRG.text section is assumed to be H'0000 8000. Also the start address of the exception handler address section is assumed to be the address that adds the respective interrupt handler address to the transfer destination base address H'FEDF E000

Figure 4.1 shows the Location of Link Directive File.

Figure 4.2 shows the Example of Creation and Section Setting for Link Directive File.

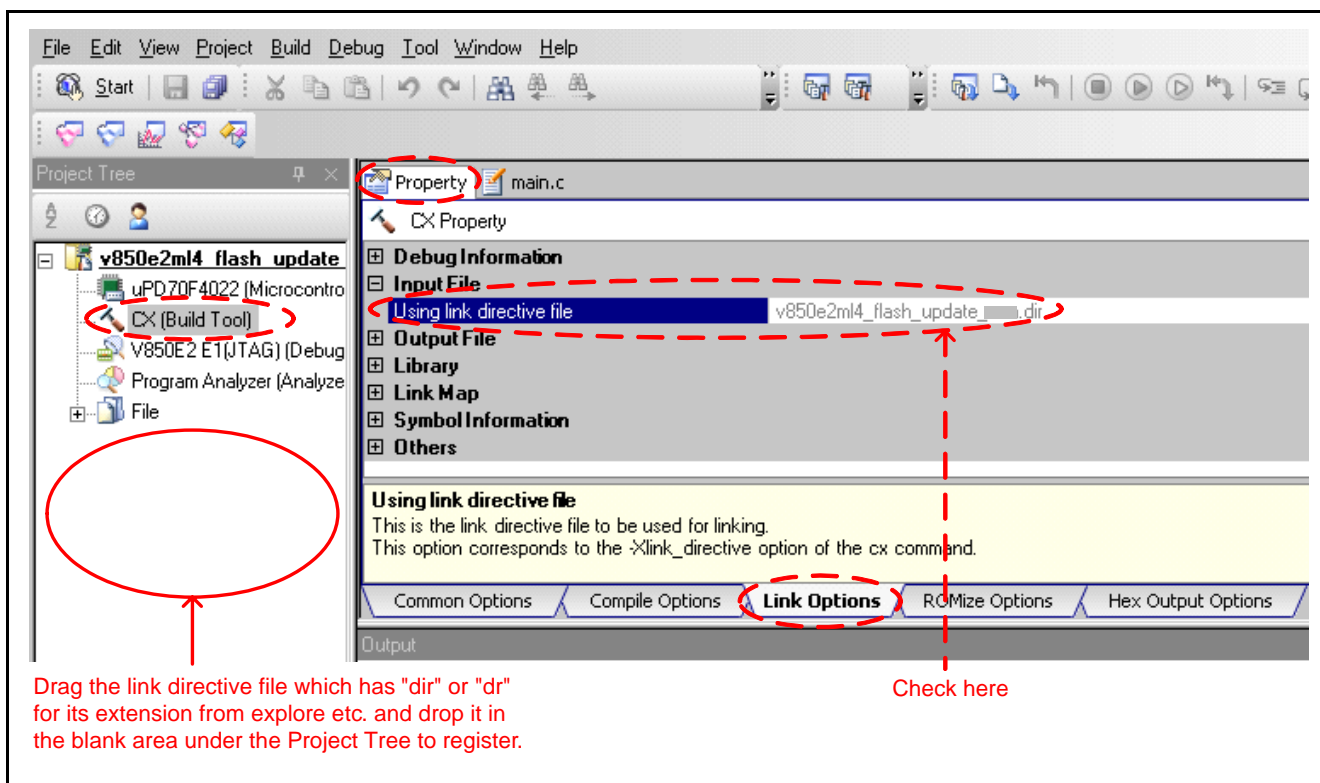


Figure 4.1 Location of Link Directive File



```

SCONST:!!LOAD ?R {
.sconst = $PROGBITS ?A .sconst ;
};
CONST:!!LOAD ?R V0x00001100 {
.const = $PROGBITS ?A .const ;
FSL_CONST.const = $PROGBITS ?A FSL_CONST.const ; # FSL area
};
TEXT:!!LOAD ?RX {
.pro_epi_runtime = $PROGBITS ?AX .pro_epi_runtime ;
.text = $PROGBITS ?AX .text ;
};
# Spare area
SparePRG:!!LOAD ?RX V0x00006000 {
SparePRG.text = $PROGBITS ?AX V0x00006000 SparePRG.text ;
};
# Reprogram area
MasterPRG:!!LOAD ?RX V0x00008000 {
MasterPRG.text = $PROGBITS ?AX V0x00008000 MasterPRG.text ;
};
DATA:!!LOAD ?RW V0xfedf0000 {
.data = $PROGBITS ?AW .data ;
.sdata = $PROGBITS ?AWG .sdata ;
.sbss = $NOBITS ?AWG .sbss ;
FSL_DATA.bss = $NOBITS ?AW FSL_DATA.bss ; # FSL use area
.bss = $NOBITS ?AW .bss ;
};
SEDATA:!!LOAD ?RW {
.sedata = $PROGBITS ?AW .sedata ;
.sebss = $NOBITS ?AW .sebss ;
};
SIDATA:!!LOAD ?RW {
.tidata.byte = $PROGBITS ?AW .tidata.byte ;
.tibss.byte = $NOBITS ?AW .tibss.byte ;
.tidata.word = $PROGBITS ?AW .tidata.word ;
.tibss.word = $NOBITS ?AW .tibss.word ;
.tidata = $PROGBITS ?AW .tidata ;
.tibss = $NOBITS ?AW .tibss ;
.sidata = $PROGBITS ?AW .sidata ;
.sibss = $NOBITS ?AW .sibss ;
};
# Program area allocated to RAM
RAM_PROG:!!LOAD ?RX V0xfedfc000 {
FSL_CODE.text = $PROGBITS ?AX FSL_CODE.text ;
FSL_CODE_ROMRAM.text = $PROGBITS ?AX FSL_CODE_ROMRAM.text ;
FSL_CODE_RAM.text = $PROGBITS ?AX FSL_CODE_RAM.text ;
FSL_CODE_RAM_USRINT.text = $PROGBITS ?AX FSL_CODE_RAM_USRINT.text ;
FSL_CODE_RAM_USR.text = $PROGBITS ?AX FSL_CODE_RAM_USR.text ;
FSL_CODE_RAM_EX_PROT.text = $PROGBITS ?AX FSL_CODE_RAM_EX_PROT.text ;
};
# Exception handler area allocated to RAM
INTRAM:!!LOAD ?RX V0xfedfe000 L0x00001080 {
INTP1RAM.text = $PROGBITS ?AX V0xfedfe170 H0x00000000a INTP1RAM.text ;
INTTAUA0I0RAM.text = $PROGBITS ?AX V0xfedfe3b0 H0x00000000a INTTAUA0I0RAM.text ;
INTUARTJ0ISRAM.text = $PROGBITS ?AX V0xfedfea50 H0x00000000a INTUARTJ0ISRAM.text ;
INTUARTJ0IRRAM.text = $PROGBITS ?AX V0xfedfea60 H0x00000000a INTUARTJ0IRRAM.text ;
};
__tp_TEXT@ %TP_SYMBOL ;
__gp_DATA@ %GP_SYMBOL &__tp_TEXT { DATA } ;
__ep_DATA@ %EP_SYMBOL ;

```

← Create section for FSL area in ROM

← Create segment and section for spare area in ROM

← Create segment and section for reprogram area in ROM

← Create section for FSL use area in RAM

← Create segment and section for FSL area and user program area in RAM

← Create segment and section for exception handler in RAM

Figure 4.2 Example of Creation and Section Setting for Link Directive File

### 4.2.2 Setting for Non-use of Prologue/Epilogue Library

The CubeSuite+ executes setting for non-use of the prologue/epilogue library. Select "CX (Build Tool)" under the Project Tree, and click "Compile Options" tab in the Property. Select "No (-Xpro\_epi\_runtime=off)" for "Use prologue/epilogue library" in "Optimization (Details)".

Figure 4.3 shows the Location of Setting Non-Use of Prologue/Epilogue Library.

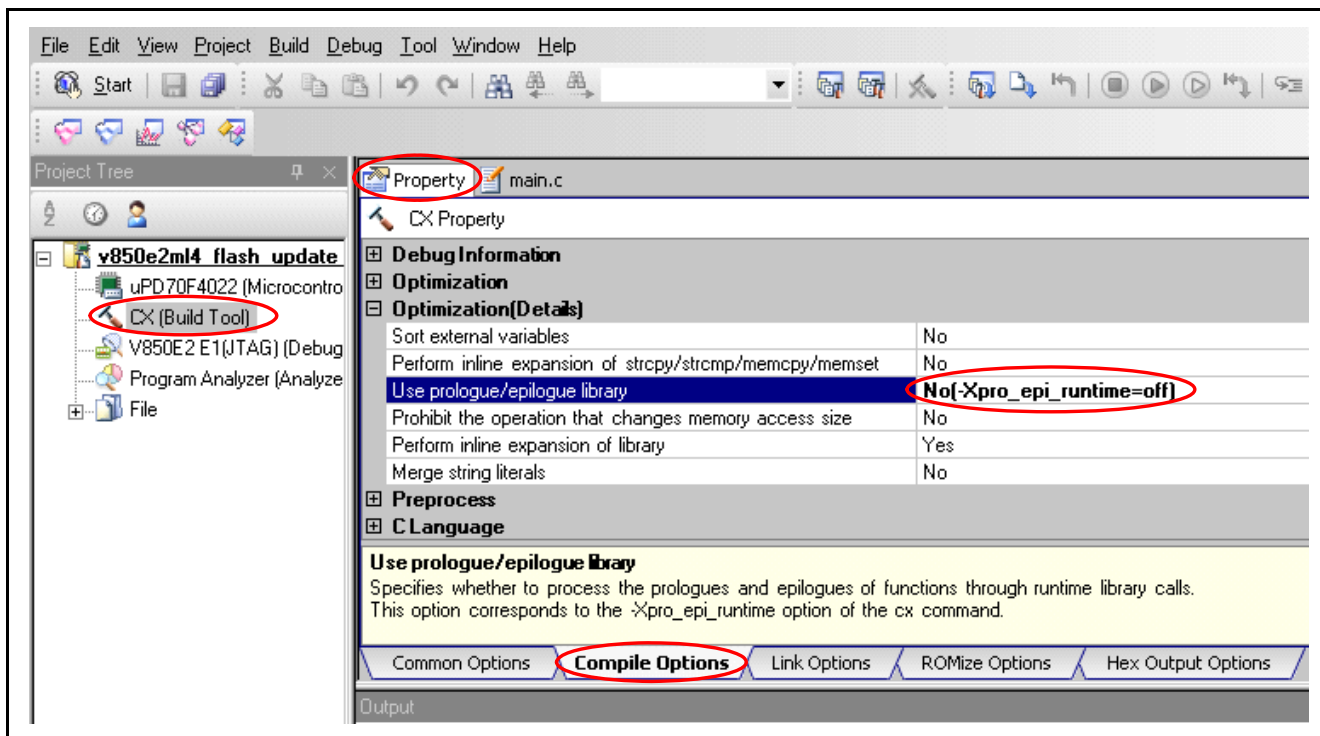


Figure 4.3 Location of Setting Non-Use of Prologue/Epilogue Library

### 4.2.3 Setting for ROMization of Section in RAM

The setting for CubeSuite+ is required for ROMization to expand the section in RAM. Select "CX (Built Tool)" under the Project Tree, and click "ROMize Options" tab in the "Property". From "Text sections included rompssec section", specify the section required for ROMization out of the sections to be assigned in RAM. Write the section names (one section per line) in the "Text Edit" window shown by clicking the "..." button on the right.

Figure 4.4 shows the Setting for Romization of Section in RAM.

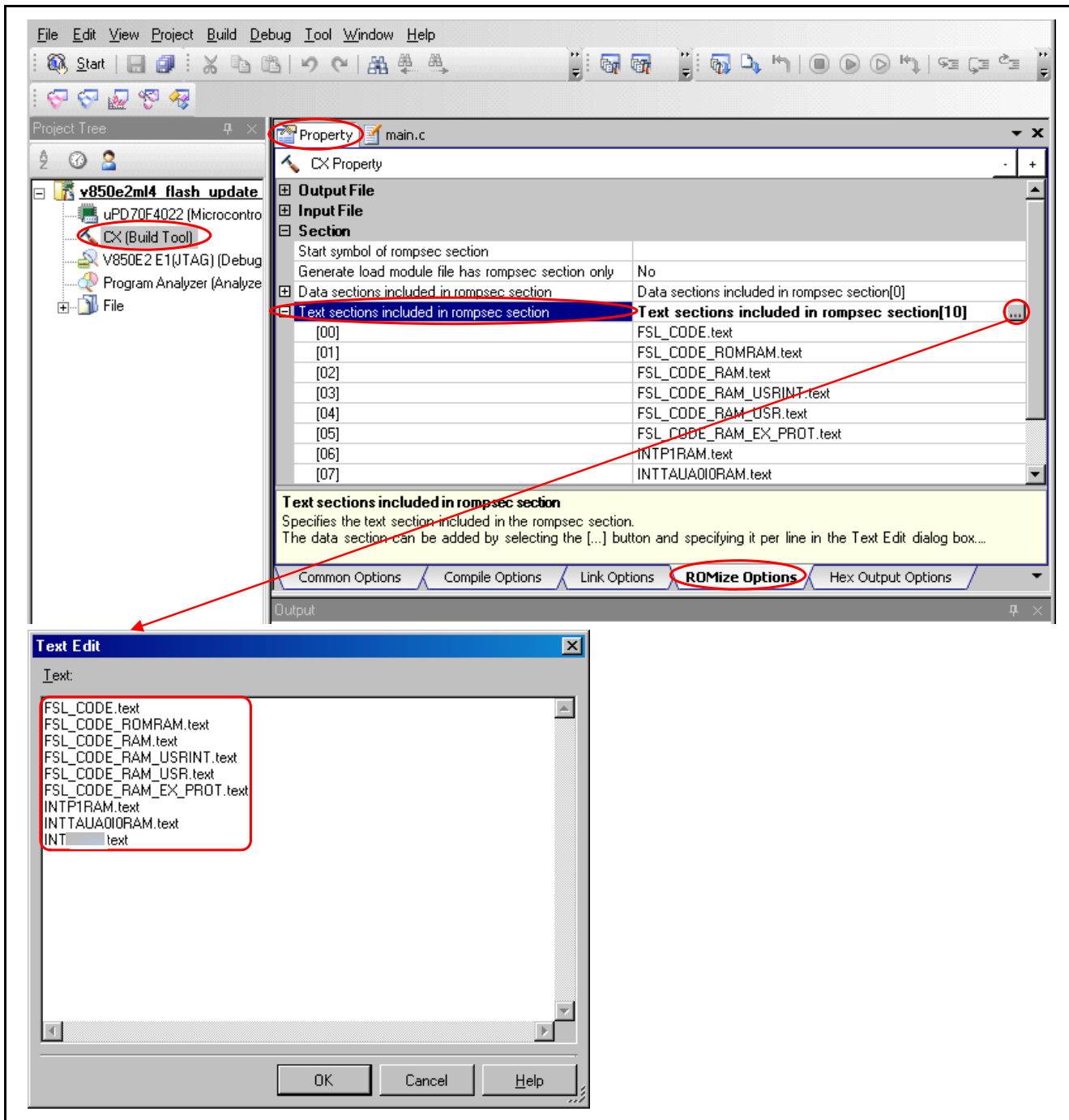


Figure 4.4 Setting for Romization of Section in RAM

#### 4.2.4 Setting for Far Jump Function

In the V850E2/ML4, the end address of the flash memory and the start address of the on-chip RAM are separated more than 2MB. In the CX compiler, when jumping to the area more than  $\pm 2$ MBs away at the time of function call, the far jump option should be specified to the call destination function. In this sample code, the far jump option is specified to the functions called from the ones on the flash memory out of the functions allocated in the on-chip RAM and all interrupt handlers to be used.

To specify the far jump option, create the file which lists the functions to be specified (far jump calling function list file) and specify the file name in the compile option "-Xfar\_jump". To set in the CubeSuite+, select "CX (Built Tool)" under the Project Tree, and click "Compile Options" tab in the Property. Click "..." button shown on the right side of "Far Jump file names" in "Output Code", and write the path of the created far jump calling function list file. (Note that ".fjp" is recommended for the extension of the far jump calling function list file.)

In the far jump calling function list file, write one function name per line. The function name should have "\_" (underscore) at the beginning of the function name with C language. Note that if "{all\_interrupt}" is written, all interrupt handler functions are subject for the far jump calling functions. For creation of far jump calling function file, refer to "3.3.3 far jump function" in "CubeSuite+ V1.03.00 Integrated Development Environment User's manual: Coding (CX compiler)"

Figure 4.5 shows the Location of Far Jump Calling Function File.

Figure 4.6 shows the Example of Creation of Far Jump Calling Function File.

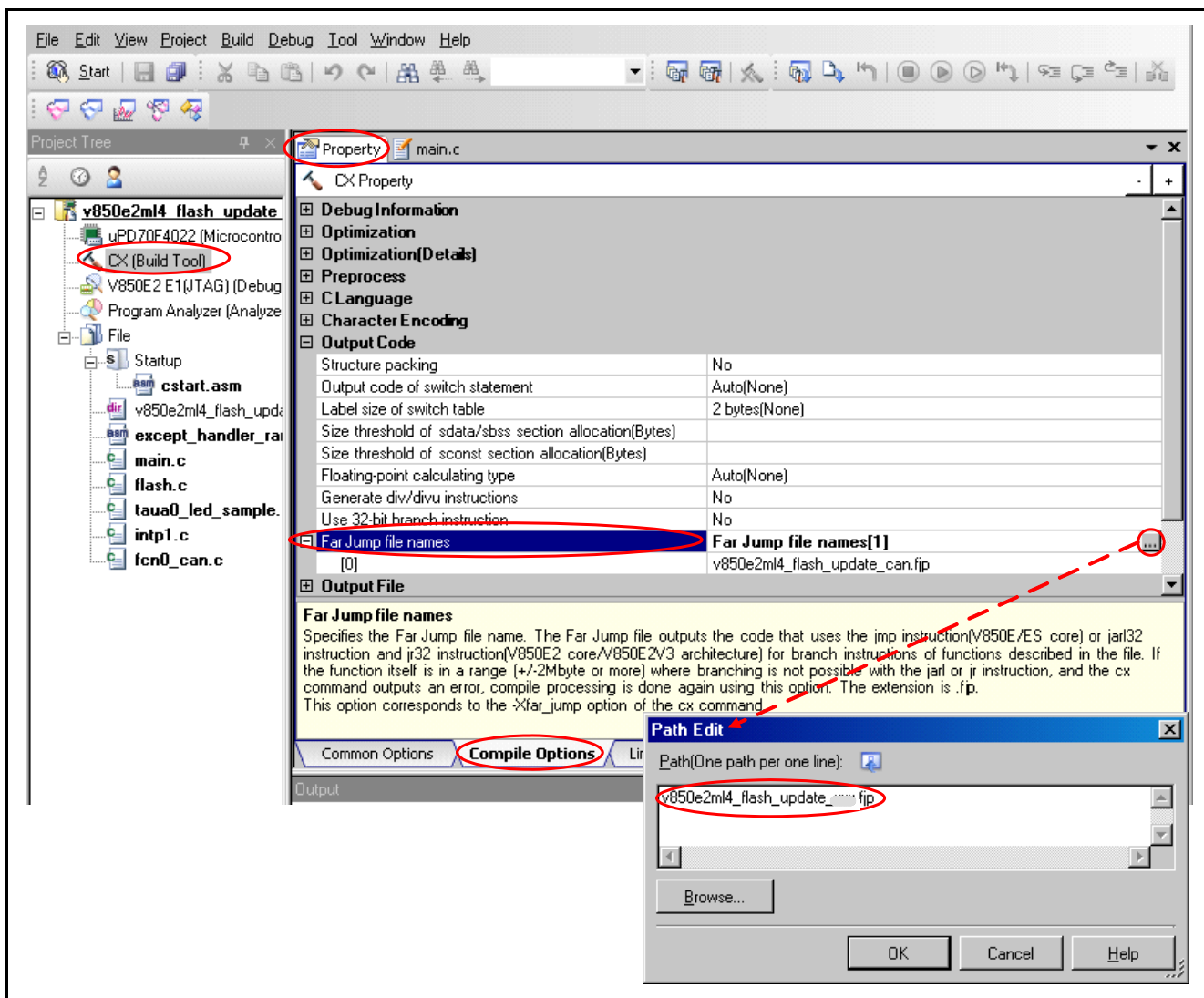


Figure 4.5 Location of Far Jump Calling Function File

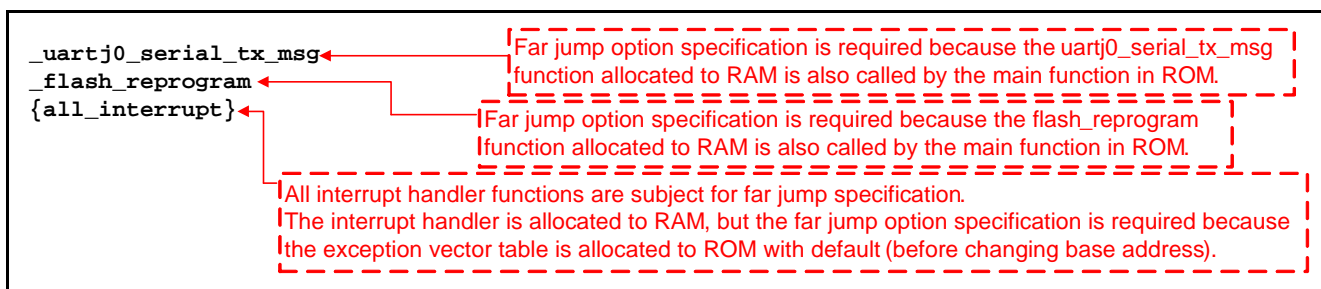


Figure 4.6 Example of Creation of Far Jump Calling Function File

### 4.2.5 Setting for Startup Routine

The stack used in this sample program requires larger area than the stack size (512 bytes) which is set in the standard startup routine. In the standard startup routine, the function "\_rcopy" (ROMize processing) is executed to develop the data with initial value and the program allocated in RAM. However, when executing the ROMize processing for the program area, initialize (clear to 0) the 16-byte boundary area of program destination before executing "\_rcopy". In this sample program, the initialization processing for the stack size change and the 16-byte boundary area of program destination is added for the assembler source file "cstart.asm" in which the standard startup routine is written.

When switching the standard startup routine, create the user-created assembler source file in which the startup routine is written to register on the CubeSuite+ project. Right click "startup" in "file" under the Project tree, then the menu will appear to add the startup routine source file.

Figure 4.7 shows the Location of Startup Routine.

Figure 4.8 shows the Example of Startup Routine Preparation (Excerpt from cstart.asm).

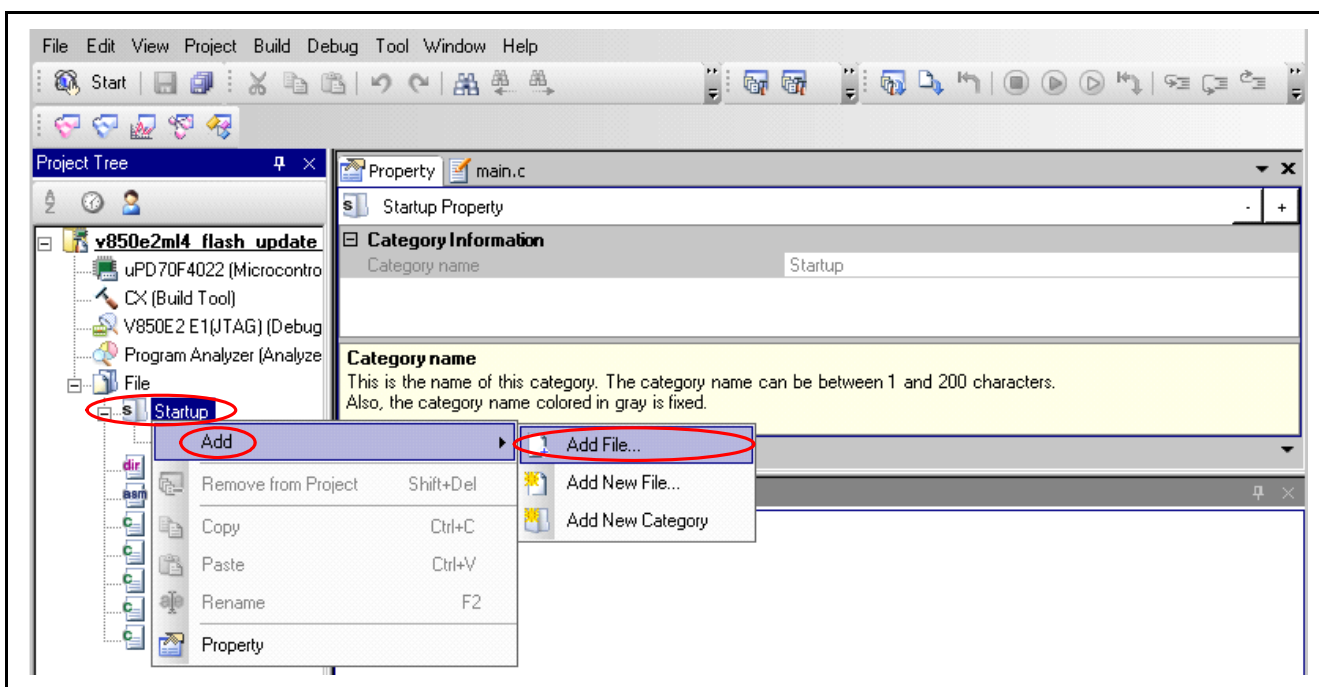


Figure 4.7 Location of Startup Routine

```

:
: (Excerpt from cstart.asm)
:
#-----
#   system stack
#-----
STACKSIZE .set 0x500
.dseg bss
.align 4
__stack: .ds (STACKSIZE)

#-----
#   RESET vector
#-----

RESET .cseg text
      jr    __start

      .cseg text
      .align 4
__start:
      mov32 #__tp_TEXT, tp      ; set tp register
      mov32 #__gp_DATA, gp     ; set gp register offset
      add   tp, gp             ; set gp register
      mov32 #__stack+STACKSIZE, sp ; set sp register
      mov32 #__ep_DATA, ep     ; set ep register

      mov32 #__PROLOG_TABLE, r12 ; for prologue/epilogue runtime
      ldsr  r12, 20             ; set CTBP (CALLT base pointer)

      jarl  __hdwinit, lp       ; initialize hardware

      mov32 #__sbss, r6         ; clear sbss section
      mov32 #__esbss, r7
      jarl  __zeroclr, lp

      mov32 #__sbss, r6         ; clear bss section
      mov32 #__ebss, r7
      jarl  __zeroclr, lp

      mov32 0xfedfc000, r6      ; clear ram_prog section for e2core prefetch processing
      mov32 0xfedffffff, r7
      jarl  __zeroclr, lp

:
: (Continued)
:

```

Change the stack size to the one required for execution of FSL and user program

Clear the periphery of the area to be used as a program in RAM to zero before executing the \_rcopy.

Figure 4.8 Example of Startup Routine Preparation (Excerpt from cstart.asm)

#### 4.2.6 Precautions for Interrupts Generated During Use of FSL

When accessing to the data using the gp register or the ep register in the interrupt processing generated during the use of the FSL, set appropriate values to the gp register or the ep register before accessing to the data. The saving process for the gp register or the ep register is required before setting the appropriate values to the registers. Furthermore, the restoring process for the gp register or the ep register is required before returning from the interrupt processing. If the said measures are not executed, the data access using the gp register or the ep register cannot be operated properly.

- Sections when accessing to the gp register as a base address:  
(The created global variables without section specification will be allocated to .sdata or .sbss.)
  - .data
  - .bss
  - .sdata
  - .sbss
  
- Sections when accessing to the ep register as a base address:
  - .sdata
  - .sebss
  - .sidata
  - .sibss
  - .tidata.byte
  - .tibss.byte
  - .tidata.word
  - .tibss.word

This sample program does not use a section which accesses to the ep register as a base address and therefore the saving, setting, and restoring processes for the ep register are not executed in the interrupt processing. The V850E2/ML4 does not require the saving, setting, and restoring of the gp register when using the FSL.

When changing the microcomputer or using the above sections, the saving, setting, and restoring of the gp register or ep register may be necessary in the interrupt processing. Cautions are required when applying.



## 5. Hardware

### 5.1 Pins Used

Table 5.1 lists the Pins Used and Their Functions.

**Table 5.1 Pins Used and Their Functions**

Pin Name	I/O	Function
P2_12/RXD0F	<b>Input</b>	Serial data input
P2_13/TXD0F	<b>Output</b>	Serial data output
P2_3/INTP1	<b>Input</b>	INTP1 interrupt

## 6. Software

### 6.1 Operation Overview

This sample program receives a program file data for update with Intel expanded hex format using serial communication, and reprograms the program in the flash memory area. This section describes its operation overview.

#### 6.1.1 Setting for Section Assignment

The access to the flash memory is prohibited while the flash memory is reprogrammed. All programs that are used during the reprogram of flash memory should be transferred to the area except flash memory. This sample program sets section assignment to transfer all the sections used during the reprogram to the on-chip RAM.

Table 6.1 lists the Sections Used During Flash Memory Reprogram.

**Table 6.1 Sections Used During Flash Memory Reprogram**

Section Name	Program Details	Function Name
FSL_CODE_ROMRAM.text, FSL_CODE_RAM.text, FSL_CODE_RAM_EX_PROT.text	FSL area	Flash function
FSL_CODE_RAM_USRINT.text	User program interrupt section for RAM	uartj0_serial_rx_isr, flash_store_serial_data, hex2bin, intp1_isr, taua0_ch0_interval_timer_isr
FSL_CODE_RAM_USR.text	User program section RAM	uartj0_serial_tx_msg, flash_reprogram, flash_init, flash_activate, flash_modecheck, flash_erase, flash_write, flash_iverify, flash_end, flash_set_flgmd0
INTP1RAM.text, INTTAUA0I0RAM.text, INTUARTJ0ISRAM.text, INTUARTJ0IRRAM.text	Jump instruction to interrupt handler function	None

This sample program additionally assigns a section area to store a spare program as a solution when the flash memory reprogram processing failed to reprogram properly such as abort without any intention. For the reprogram area and the spare area before receiving data (initial state), the programs which have the same processing are stored in respective area.

Table 6.2 lists the Functions and Sections Specifying Addresses on Flash Memory.

**Table 6.2 Functions and Sections Specifying Addresses on Flash Memory**

Area	Start Address (block number)	Store Function Name	ROM Section Name
Reprogram area	H'0000 8000 (8)	taua0_led_sample	MasterPRG.text
Spare area	H'0000 6000 (6)	taua0_led_spare	SparePRG.text

6.1.2 Overview of Reprogramming Flash Memory

Figure 6.1 shows the Overview of Reprogramming Flash Memory.

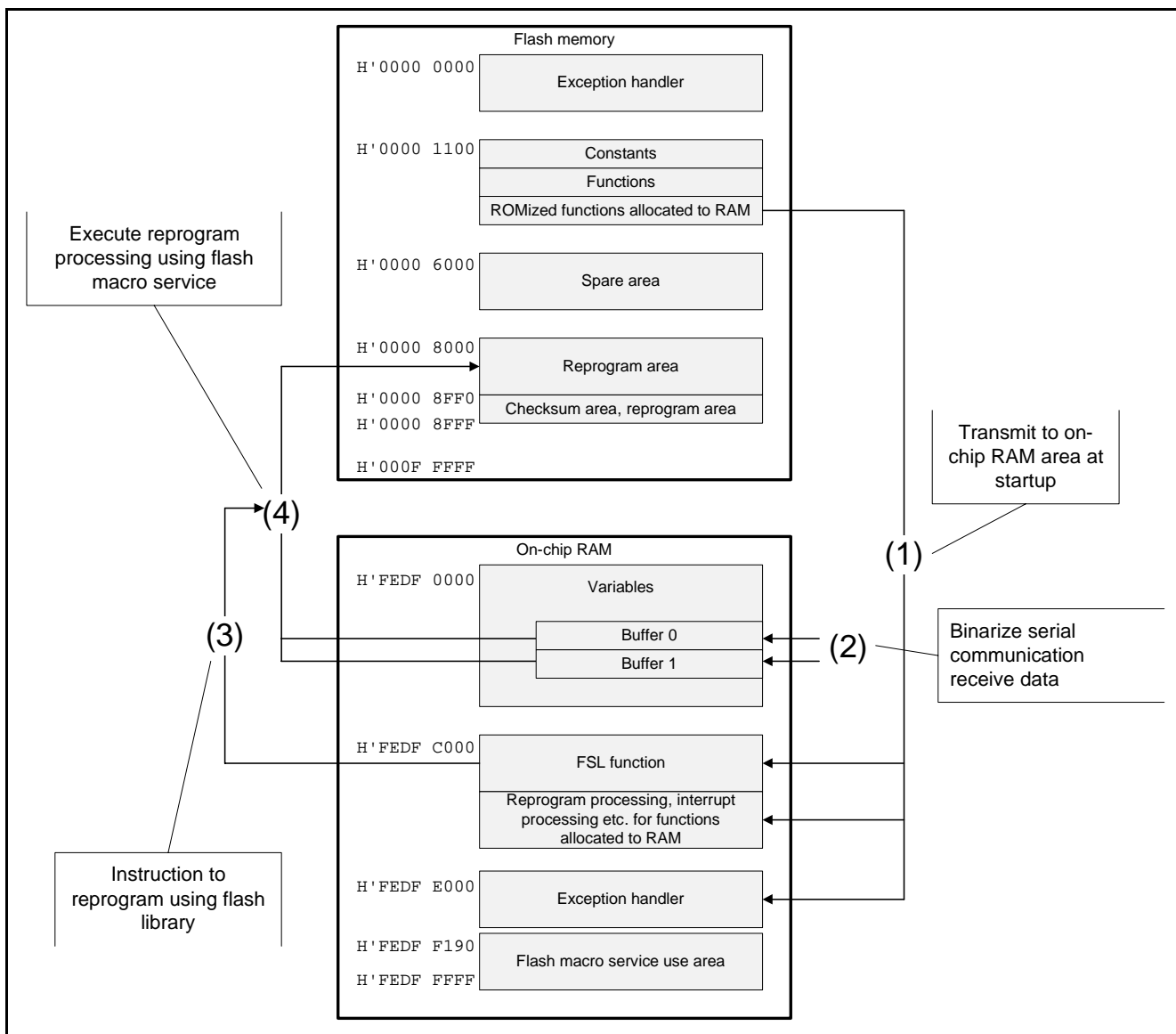


Figure 6.1 Overview of Reprogramming Flash Memory

1. After cancelling the reset, the \_\_S\_romp (ROMized section group) is copied to the on-chip RAM during the cstart.asm processing before starting the main function.
2. The Intel Extend Hex format data received via serial communication is stored to the on-chip RAM with the state of binary data which executes writing.
3. The operation for the flash macro service is executed by the flash library function which is assigned to the on-chip RAM.
4. The flash macro service executes the reprogram processing of on-chip flash memory.

### 6.1.3 Process from Startup to Normal Operation

After the system activation, execute initializations in the main processing, and transmit a message "Generate INTP1 interrupt for transition to flash programming event." to the host. Then call the checksum judgment function to judge the program code in the reprogram area.

The checksum of this sample program uses "Program code size" and "Checksum data" that a program was added to one byte at a time. The checksum judgment function adds a program one byte at a time with the start address (H'0000 8000) in the reprogram area for the number of program data size. The calculation result is compared with the checksum judgment data calculated when received a data (Stored in the last 16-byte area of MasterPRG.text. Refer to 6.1.6 for the details). The program in the reprogram area will be executed when the calculation result matches the said data, and the one in the spare area will be executed if there is a difference.

### 6.1.4 Flash Reprogram Processing after INTP1 Interrupt Input

When the INTP1 interrupt (rising edge detection/ INTP1 switch push down on the board) is generated, moves to flash reprogram processing.

In the flash reprogram processing, the message "--> INTP1 detected!" is transmitted to the host to erase the reprogram area. Then the message "Send subroutine code to update program in Intel expanded hex format." is transmitted to the host to enter wait state for data reception from the host.

In the wait state for data reception, flag variables are used by polling to detect if the flash write is enabled or disabled. When receiving program file data for update with Intel expanded hex format from the host, the data receive processing (later described) is executed, and the data is stored into the write data store buffer (write buffer). When the write buffer becomes full, the buffer data will be written to the flash memory.

This sample program provides a double structured write buffer. Regarding "Storing write data during data receive processing" and "Writing to the flash memory", each processing should be executed by switching the write buffer to be used.

### 6.1.5 Data Receive Processing

After entering in the wait state for data reception, the UARTJ0 receive interrupt is generated every time the serial communication data is received from the host. When the UARTJ0 interrupt is generated, the received data will be stored into the serial receive data store buffer (receive buffer) in the order received. When receiving the line feed code, the data that has been stored in the receive buffer is considered as a record data for one-line. The following data receive processing is executed to extract write data necessary for updating.

The data receive processing is described as follows referring to Figure 6.2 that shows the Example of Data with Inter Expanded Hex Format. (The data shown in Figure 6.2 is color coded depending on its function.)

```

:04000005000013C81C
:020000040000FA
:2080000E0570584CA5EEFFF605F0484E0670583CC6EEFFF606F0483407640FF2E7F054609
:20802000CF86EFFF408E40FF71870546E0970580929E1000609F0480405681FF6A070082E5
:208040002B06FAFF0000406681FF6C5F4082206EFF3F606F00C44076FFF0E7F66608F86C8
:1A806000F00408EFFF518766604096FFFD2BF6660019A609FC4C57F00C0
:00000001FF

```

Figure 6.2 Example of Data with Inter Expanded Hex Format

- For the processing of each line, determine if the 1st character of the data in the receive buffer shows ":". If it shows ":", judge the 8th and 9th characters (red) as Intel expanded hex format. If the 1st character does not show ":", the record data become invalid, and returns to wait state for receive data. When the 8th character does not show "0", the record data also become invalid, and returns to wait state.
- The 8th and 9th characters (red) of the first line show "05". This "05" indicates the start linear address record which does not have a program data. When received the start linear address record, return to the wait state for receive data until the next entire record (line data) will be displayed.
- The 8th and 9th characters (red) of the second line show "04". This "04" indicates the extended linear address record which does not have a program data. When received the extended linear address record, return to the wait state for receive data until the next entire record will be displayed.
- When the entire 3rd line of the record is displayed, the line is determined as a "data record" because the 8th and 9th characters (red) show "00". The type of the record can be determined by the numbers from the start to 9th of each record with Intel expanded hex format.
- The 2th and 3rd characters (blue) of the record indicate the hex for 1-byte of the record size. The four characters from 4th to 8th (green) indicate the lower 2 bytes of the start data store address of the record.
- Regarding the 10th and later characters (orange) of the record, each two characters indicates 1 byte. In the data receive processing, the 10th and later characters (orange) is converted into binary data every 2 characters (call "text binary conversion processing"), store the 1 byte data after the conversion into the write buffer in the order converted. Add the one byte data for the checksum judgment (checksum data), and count the amounts of the data as a program code size. When repeated these processing before the last two characters (black) of the record, return to the wait state for receive data until the next entire record will be displayed.
- When the 8th and 9th (red) characters of the record data show "01", it means "end record" (the bottom line in Figure 6.2). When the end record is shown, terminate the data receive processing without storing receive data. However, if the data size in the write buffer is less than 16 bytes (unit of flash write) at this point, add H'FF to make the buffer size 16 bytes.

This sample program provides a double structured write buffer with 16-byte size. Every time the store data in a write buffer becomes full at 16 bytes, the store destination is switched to another write buffer during the data receive processing. When the said buffer becomes full, the buffer data is written to the flash memory during flash reprogram event processing. Writing to the flash memory is executed by polling waiting for receive data, not by an interrupt processing. When switching the buffer at full, set flag variables which indicate writability.

### 6.1.6 Processing after Data Deception/Reprogramming

When the end record is determined during data receive processing and the write of flash memory for the receive data is terminated, the V850E2/ML4 leaves from the wait state for data reception in the flash reprogram event processing, and writes the data for checksum judgment calculated at the time of data reception (program code size and checksum data/ 2 bytes for each) the flash memory. In this sample program, the data for checksum judgment is stored the last 4 bytes of the reprogram area H'0000 8FF0 to H'0000 8FF3 (H'0000 8FF0 to H'0000 8FF1 for the program code size and H'0000 8FF2 to H'0000 8FF3 for the checksum data).

After writing the data for checksum judgment, a message is transmitted to the host and the V850E2/ML4 enters wait state for reset.

6.1.7 Communication Control Sequence

Figure 6.3 shows the Communication Control Sequence.

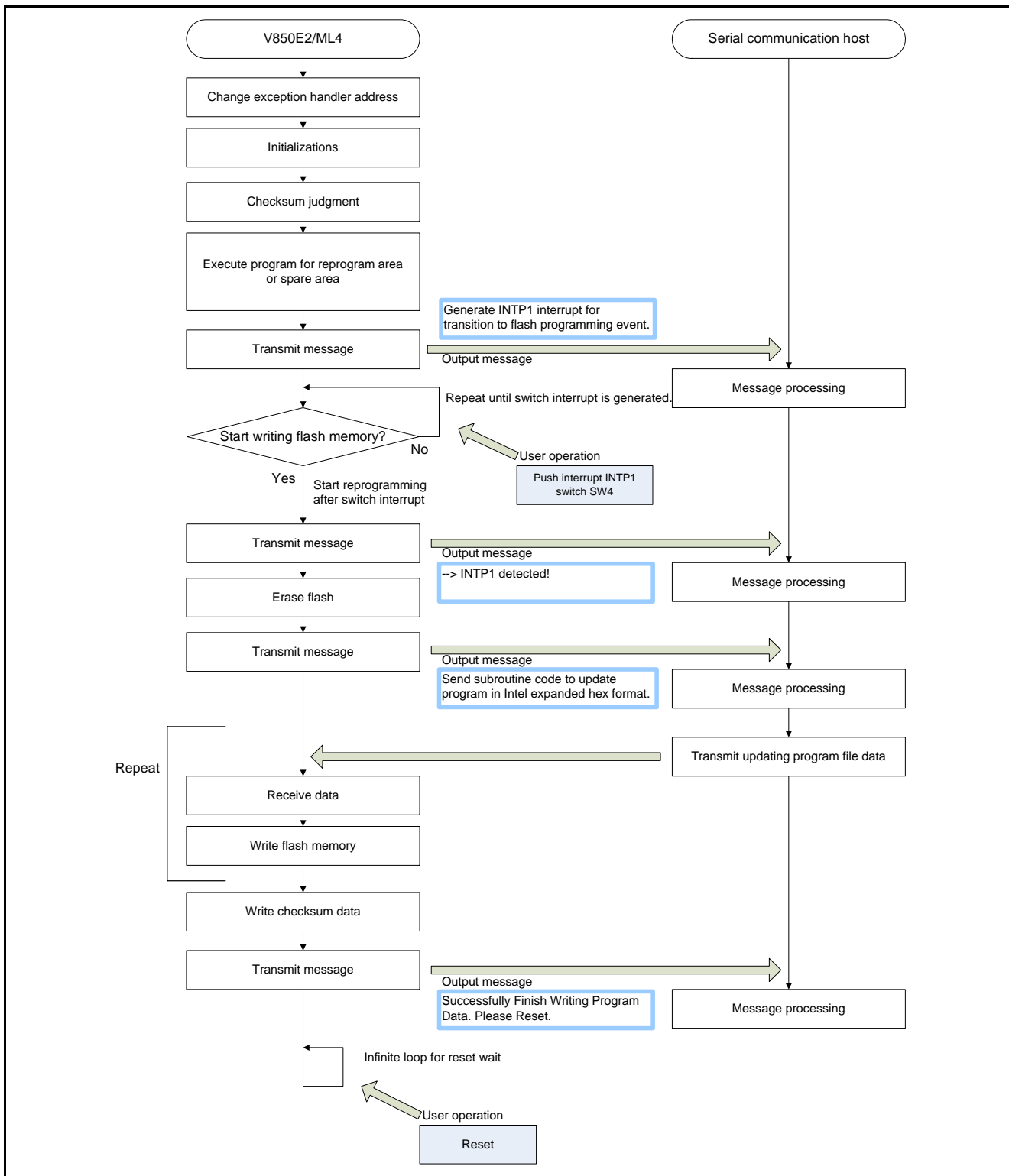


Figure 6.3 Communication Control Sequence

## 6.2 File Composition

Table 6.3 lists the Files Used in the Sample Code. Files generated by the integrated development environment are not included in this table.

**Table 6.3 Files Used in the Sample Code**

File Name	Outline	Remarks
main.c	Main processing	
intp1.c	INTP1 interrupt processing	
flash.c	Processing related to flash reprogram	
uartj0_serial.c	Processing related to UARTJ	
taua0_led_sample.c	Sample program for updating, LED blink port processing	
flash.h	Common header for flash memory reprogram processing	
r_typedefs.h	Fixed length integer type definition header	
FSL.h	FSL header file	
except_handler_ram.asm	Exception handler in RAM*	Jump to interrupt processing function from RAM
cstart.asm	Startup routine	Change stack size by standard startup routine, and add initialization of program area in RAM
libFSL_T05_REC_R32.lib	FSL library (32 register mode)	
v850e2ml4_flash_update_uartj.dir	Link directive setting file	
v850e2ml4_flash_update_uartj.fjp	Far jump calling functions file	

[Note] \* Defines the jump instruction from the interrupt handler address to the interrupt handler function to be allocated on the exception handler.

### 6.3 Constants

Table 6.4 and Table 6.5 list the Constants Used in the Sample Code.

**Table 6.4 Constants Used in the Sample Code**

Constant Name	Setting Value	Contents
RET_OK	0	Normal end
RET_ERR	-1	Error end
RET_ERR_FLASH_ACTIVATE	-1	Failure to start flash environment
RET_ERR_FLASH_MODECHECK	-2	Failure to check FLMD0 pin
RET_ERR_FLASH_ERASE	-3	Failure of erase processing
RET_ERR_FLASH_WRITE	-4	Failure to write
RET_ERR_FLASH_IVERIFY	-5	Failure of internal verification
RET_ERR_FLASH_DEACTIVATE	-6	Failure to terminate flash environment
RET_ERR_FLASH_FLMD0_HIGH	-7	Failure to set High level for FLMD0 pin
RET_ERR_FLASH_FLMD0_LOW	-8	Failure to set Low level for FLMD0 pin
RET_ERR_FLASH_HEX_LINESIZE	-9	Abnormal numbers of hex file line data
RET_ERR_FLASH_HEX_DATA	-10	Abnormal hex file program data
BLOCK_MASTER_PRG	8	Block number of reprogram area
TOP_ADDR_MASTER_PRG	H'00008000	Start address of reprogram area
SIZE_MASTER_PRG	H'1000	Reprogram area size (4KB)
SIZE_WRITE	16	Write specification size
TOP_ADDR_MASTER_PRG_CHKSUM	TOP_ADDR_MASTER_PRG + SIZE_MASTER_PRG - SIZE_WRITE	Start address of checksum area (H'00008FF0)
TOP_ADDR_EXT_HANDLER	H'FEDF E000	Start address of exception handler address for transfer destination



Table 6.5 Constants Used in the Sample Code

Constant Name	Setting Value	Contents
FLASH_STATUS_FLMD0_HIGH	H'01	FLMD0 High setting completion status (valid pull-up)
FLASH_STATUS_FSL_ACTIVE	H'02	FSL start status
HEXDATA_POS_RECMARK	0	Record mark position of hex data
HEXDATA_POS_BYTE_NUM	1	Position for the number of bytes of hex data
HEXDATA_POS_RECTYPE_UPPER	7	The upper digit position of hex data record type
HEXDATA_POS_RECTYPE_LOWER	8	The lower digit position of hex data record type
HEXDATA_POS_CODE_TOP	9	Start position of hex data code
SIZE_BUF_RX_DATA	525	Receive data store buffer size (total of the followings) Record mark: 1 character The number of bytes: 2 characters Location address: 4 characters Record type: 2 characters Code: 512 characters (max) Checksum: 2 characters Return (\r) + New line (\n): 2 characters
PORT_BIT_P1_4	H'0010	Bit position of port function setting P1_4
PORT_BIT_P2_3	H'0008	Bit position of port function setting P2_3
PORT_BIT_P2_12	H'1000	Bit position of port function setting P2_12
PORT_BIT_P2_13	H'2000	Bit position of port function setting P2_13

## 6.4 Variables

Table 6.6 lists the Global Variables.

**Table 6.6 Global Variables**

Type	Variable Name	Contents	Function Used
uint8_t	g_flag_start_flash_reprog	Start flag for writing flash memory	main, intp1_isr
fsl_status_t	g_error_fsl_status	Store FSL error	main, flash_activate, flash_modecheck, flash_erase, flash_write, flash_iverify
uint32_t	g_addr_write_error	Write error address	main, flash_write
uint8_t	g_flag_w_data_buf0_full	Write buffer 0 full flag	flash_reprogram, flash_store_serial_data
uint8_t	g_flag_w_data_buf1_full	Write buffer 1 full flag	flash_reprogram, flash_store_serial_data
uint8_t	g_status_end_record	End record receive flag	flash_reprogram, flash_store_serial_data
uint16_t	g_chksm_size	Program code size for write data	flash_reprogram, flash_store_serial_data
uint16_t	g_chksm_data	Checksum data of write data	flash_reprogram, flash_store_serial_data
uint8_t	g_buf_write_data0 [SIZE_WRITE]	Write data store buffer 0	flash_reprogram, flash_store_serial_data
uint32_t	g_cnt_store_buf_w_data0	Data counts of write data store buffer 0	flash_reprogram, flash_store_serial_data
uint8_t	g_buf_write_data1 [SIZE_WRITE]	Write data store buffer 1	flash_reprogram, flash_store_serial_data
uint32_t	g_cnt_store_buf_w_data1	Data counts of write data store buffer 1	flash_reprogram, flash_store_serial_data
uint32_t	g_index_rx_data	Receive data storage location index	flash_reprogram, flash_store_serial_data
uint8_t	g_buf_rx_data [SIZE_BUF_RX_DATA]	Receive data store buffer	flash_store_serial_data
int8_t	g_status_store_error	Error flag	flash_reprogram, flash_store_serial_data
uint8_t	g_flag_flash_status	Flash environment status	flash_init, flash_activate, flash_end
char	g_msg_sendcode[]	Program transmit request message	flash_reprogram

## 6.5 Functions

Table 6.7 lists the Functions.

**Table 6.7 Functions**

Function Name	Outline
main	Main processing
except_handler_addr_set	Switching processing of exception handler base address
check_sum_check	Checksum judgment of reprogram area
intp1_init	Initialization of INTP1 interrupt
intp1_isr	INTP1 interrupt processing
flash_reprogram	Flash reprogram processing
flash_init	Initialization of flash environment
flash_activate	Start processing of flash environment
flash_modecheck	Checking processing of FLMD0 pin using FSL
flash_erase	Erase processing for specified block
flash_write	Write processing from specified address
flash_iverify	Internal verification of specified block
flash_end	Termination processing of flash environment
flash_set_flmd0	Setting for FLMD0 pin level
flash_store_serial_data	Store processing of receive data conversion
hex2bin	Text binary conversion processing
taua0_led_sample	Initialization of TAUA0 for LED blink with fixed cycle (sample function in reprogram area)
taua0_led_spare	Initialization of TAUA0 for LED blink with fixed cycle (sample function in spare area)
taua0_i0_interval_timer_isr *	TAUA0 interval timer interrupt processing
uartj0_serial_init	Initialization of UARTJ0
uartj0_serial_port_init	Initialization of UARTJ0 ports
uartj0_serial_tx_msg	UARTJ0 message transmit processing
uartj0_serial_rx_isr	UARTJ0 receive interrupt processing
uartj0_serial_status_isr	UARTJ0 status interrupt processing

[Notes] \* To set the store processing for received program data by serial communication above the LED flash processing, the interrupt handler function `taua0_ch0_interval_timer_isr` enables multiple interrupts. TAUA0 interval timer interrupt is set to the lower priority than FCN0 reception completion interrupt.

## 6.6 Function Specifications

The following tables list the sample code function specifications.

<b>main</b>	
<b>Outline</b>	Main processing
<b>Header</b>	
<b>Declaration</b>	void main (void)
<b>Description</b>	After initializing the variables, the exception handler address, INTP1 interrupt, and UARTJ, executes the program allocated in the reprogram area or the spare area according to the checksum judgment. Enables interrupts and outputs INTP1 interrupt request message, then execute the flash reprogram processing when INTP1 interrupt is generated. Outputs the reset request message for successful reprogram, or the error message for failure.
<b>Arguments</b>	None
<b>Return Value</b>	None
<b>except_handler_addr_set</b>	
<b>Outline</b>	Switching processing of exception handler base address
<b>Header</b>	
<b>Declaration</b>	int32_t except_handler_addr_set (uint32_t base_addr)
<b>Description</b>	After setting the value specified by the argument to the SW_BASE register, sets 1 to SET bit of the SW_CTL register. Then transfers the contents of SW_BASE register to the exception handler base address register (EH_BASE).
<b>Arguments</b>	uint32_t base_addr : Exception handler base address setting value (The lower 12-bit should be 0.)
<b>Return Value</b>	0 (RET_OK) : Normal end -1 (RET_ERR) : Argument error (The lower 12-bit is not 0.)
<b>check_sum_check</b>	
<b>Outline</b>	Checksum judgment of reprogram area
<b>Header</b>	
<b>Declaration</b>	int32_t check_sum_check (void)
<b>Description</b>	Based on the program code size or checksum data stored in the last 4 bytes (H'0000 8FF0 to H'0000 8FF3) of reprogram area, calculates sum value from the start address (H'0000 8000) of reprogram area to judge the consistency with the checksum data.
<b>Arguments</b>	None
<b>Return Value</b>	0 (RET_OK) : Checksum matched -1 (RET_ERR) : Checksum unmatched

---

intp1_init	
<b>Outline Header</b>	Initialization of INTP1 interrupt
<b>Declaration</b>	void intp1_init (void)
<b>Description</b>	Initializes INTP1 interrupt. After setting P2_3 pin function to INTP1 input, sets the interrupt request to be detected at the falling edge for input using interrupt controller. Then sets INTP1 interrupt priority level.
<b>Arguments</b>	None
<b>Return Value</b>	None

---

intp1_isr	
<b>Outline Header</b>	INTP1 interrupt processing
<b>Declaration</b>	void intp1_isr (void)
<b>Description</b>	Sets the flag which indicates that INTP1 interrupt has been generated.
<b>Arguments</b>	None
<b>Return Value</b>	None

---

flash_reprogram	
<b>Outline Header</b>	Flash reprogram processing flash.h
<b>Declaration</b>	int32_t flash_reprogram (void)
<b>Description</b>	Executes initialization of the flash environment, start processing of the flash environment, checking processing of FLMD0 pin, and reprogram block erase processing. Then transmits the program transmit request message and enters into the loop for program receive wait and flash writing. When the program has been received to the last, executes the flash reprogram termination processing by writing the checksum data.
<b>Arguments</b>	None
<b>Return Value</b>	0 (RET_OK) : Normal end -1 (RET_ERR_FLASH_ACTIVATE) : Failure to start flash environment -2 (RET_ERR_FLASH_MODECHECK) : Failure to check FLMD0 pin -3 (RET_ERR_FLASH_ERASE) : Failure of erase processing -4 (RET_ERR_FLASH_WRITE) : Failure of write processing -5 (RET_ERR_FLASH_IVERIFY) : Failure of internal verification -6 (RET_ERR_FLASH_DEACTIVATE) : Failure to terminate flash environment -7 (RET_ERR_FLASH_FLMD0_HIGH) : Failure to set FLMD0 pin to High level -8 (RET_ERR_FLASH_FLMD0_LOW) : Failure to set FLMD0 pin to Low level -9 (RET_ERR_FLASH_HEX_LINESIZE) : Abnormal numbers of hex file data -10 (RET_ERR_FLASH_HEX_DATA) : Abnormal program data of hex file

---

flash_init	
<b>Outline Header</b>	Initialization of flash environment
<b>Declaration</b>	int32_t flash_init (void)
<b>Description</b>	After executing FLMD0 pin level setting function and setting FLMD0 pin to High level, initializes the self library by executing the FSL_Init function. When the flash_set_flmd0 function becomes an error, the RET_ERR_FLASH_FLMD0_HIGH will be returned.
<b>Arguments</b>	None
<b>Return Value</b>	0 (RET_OK) : Normal end -7 (RET_ERR_FLASH_FLMD0_HIGH) : Failure to set FLMD0 pin to High level
flash_activate	
<b>Outline Header</b>	Start processing of flash environment
<b>Declaration</b>	int32_t flash_activate (void)
<b>Description</b>	Starts the flash environment by calling the FSL_FlashEnv_Activate function. In case of normal end, sets the bit which indicates that the flash environment has been started to the g_flag_flash_status of the global variable, and then the RET_OK is returned to terminate. When the FSL_FlashEnv_Activate function returns the value other than the FSL_OK, the return value will be stored in the g_error_fsl_status of the global variable. The RET_ERR_FLASH_ACTIVATE is returned to terminate.
<b>Arguments</b>	None
<b>Return Value</b>	0 (RET_OK) : Normal end -1 (RET_ERR_FLASH_ACTIVATE) : Failure to start flash environment
flash_modecheck	
<b>Outline Header</b>	Checking processing of FLMD0 pin using FSL
<b>Declaration</b>	int32_t flash_modecheck (void)
<b>Description</b>	Executes checking of FLMD0 pin by calling the FSL_ModeCheck function. In case of normal end, the RET_OK will be returned to terminate. When the FSL_ModeCheck function returns other than the FSL_OK, the return value will be stored in the g_error_fsl_status of the global variable. The RET_ERR_FLASH_MODECHECK is returned to terminate.
<b>Arguments</b>	None
<b>Return Value</b>	0 (RET_OK) : Normal end -2 (RET_ERR_FLASH_MODECHECK) : Failure to check FLMD0 pin

flash_erase	
<b>Outline Header</b>	Erase processing of specified block
<b>Declaration</b>	int32_t flash_erase (uint32_t start_block, uint32_t end_block)
<b>Description</b>	Executes the block erase by calling the FSL_Erase function according to the specified argument. After executing the FSL_Erase function, calls the FSL_StatusCheck function and waits until the erase processing has been completed. When the FSL_Erase function or the FSL_StatusCheck function returns the error value, the return value will be stored in the g_error_fsl_status of the global variable. The RET_ERR_FLASH_ERASE is returned to terminate.
<b>Arguments</b>	uint32_t start_block : Start block number of the range to be erased uint32_t end_block : End block number of the range to be erased
<b>Return Value</b>	0 (RET_OK) : Normal end -3 (RET_ERR_FLASH_ERASE) : Failure to erase
flash_write	
<b>Outline Header</b>	Write processing from specified address
<b>Declaration</b>	int32_t flash_write (uint8_t * src_data_addr, uint32_t dst_write_addr, uint32_t length)
<b>Description</b>	Executes writing to the flash memory by calling the FSL_Write function according to the specified argument. After executing the FSL_Write function, calls the FSL_StatusCheck function and waits until the write processing has been completed. When the FSL_Write function or the FSL_StatusCheck function returns the error value, the value will be stored in the g_error_fsl_status of the global variable. The RET_ERR_FLASH_WRITE is returned to terminate.
<b>Arguments</b>	uint8_t * src_data_addr : Start address of write data (outside the on-chip RAM) uint32_t dst_write_addr : Destination address of write data (4-word boundary) uint32_t length : Write data length (word unit, 4-word boundary, MAX: on-chip ROM size)
<b>Return Value</b>	0 (RET_OK) : Normal end -4 (RET_ERR_FLASH_WRITE) : Failure to write
flash_verify	
<b>Outline Header</b>	Internal verification of specified block
<b>Declaration</b>	int32_t flash_verify (uint32_t start_block, uint32_t end_block)
<b>Description</b>	Calls the FSL_IVerify function according to the argument to execute the internal verification of specified block. After executing the FSL_IVerify function, calls the FSL_StatusCheck function and waits until the internal verification has been completed. When the FSL_IVerify function or the FSL_StatusCheck function returns the error value, the return value will be stored in the g_error_fsl_status of global variable. Returns the RET_ERR_FLASH_IVERIFY to terminate.
<b>Arguments</b>	uint32_t start_block : Start block number of the range for verify check uint32_t end_block : End block number of the range for verify check
<b>Return Value</b>	0 (RET_OK) : Normal end -5 (RET_ERR_FLASH_IVERIFY) : Failure of internal verification

flash_end	
<b>Outline Header</b>	Termination processing of flash environment
<b>Declaration</b>	int32_t flash_end (void)
<b>Description</b>	After terminating the flash environment by calling the FSL_FlashEnv_Deactivate function, sets FLMD0 pin to Low level by calling the flash_set_flmd0 function. When the FSL_FlashEnv_Deactivate returns the error value, the RET_ERR_FLASH_DEACTIVATE will be returned. When the flash_set_flmd0 function returns the value other than 0, the RET_ERR_FLASH_FLMD0_LOW will be returned to terminate.
<b>Arguments</b>	None
<b>Return Value</b>	0 (RET_OK) : Normal end -6 (RET_ERR_FLASH_DEACTIVATE) : Failure to terminate flash environment -8 (RET_ERR_FLASH_FLMD0_LOW) : Failure to set FLMD0 pin to High level
flash_set_flmd0	
<b>Outline Header</b>	Setting for FLMD0 pin level
<b>Declaration</b>	int32_t flash_set_flmd0 (uint8_t level)
<b>Description</b>	Sets FLMD control register to switch FLMD0 pull-up/pull-down control. According to the reprogram sequence for the protect register, substitutes H'A5 for FLMD protect command register, and then substitutes the value specified by the argument for FLMD control register. After substituting the invert value, substitutes the value specified again by the argument. Checks that the register value has been changed to terminate.
<b>Arguments</b>	uint8_t level : 0x00 : Set FLMD0 pin to Low level 0x01 : Set FLMD0 pin to High level
<b>Return Value</b>	0 (RET_OK) : Normal end -1 (RET_ERR) : Error in writing operation to FLMDCNT register
flash_store_serial_data	
<b>Outline Header</b>	Store processing of receive data conversion flash.h
<b>Declaration</b>	void flash_store_serial_data (uint8_t rx_data)
<b>Description</b>	Converts the hex data to binary data every line and stores the converted data in the buffer. When the hex data for one-line is the data record, converts the data in binary form and saves it until the buffer becomes full. When the hex data for on-line is the end record, pads the remaining bytes with H'FF and sets the flag which indicates the receiving has been completed.
<b>Arguments</b>	uint8_t rx_data : Receive hex data
<b>Return Value</b>	None



hex2bin	
<b>Outline</b>	Text binary conversion processing
<b>Header</b>	
<b>Declaration</b>	int32_t hex2bin(uint8_t upper, uint8_t lower)
<b>Description</b>	Converts the text data (2 characters) to the binary data with 1 byte. When the data given to the argument is the text data with "0" to "9" or "A" to "F", it is considered as the valid data and will be converted to the binary data with "H'0 to H'F". After shifting the conversion result of the first argument (upper) to left by 4 bits and implementing the OR with the conversion result of the second argument (lower), returns it as the binary data with 1 byte.
<b>Arguments</b>	uint8_t upper : Text data for the upper 4-bit uint8_t lower : Text data for the lower 4-bit
<b>Return Value</b>	0 to 255 : Binary data with 1 byte -1 (RET_ERR) : Input data error
taua0_led_sample	
<b>Outline</b>	Initialization of TAU0 for LED blink with fixed cycle (sample function in reprogram area)
<b>Header</b>	
<b>Declaration</b>	void taua0_led_sample (void)
<b>Description</b>	Sets the port connected to the LEDs to output to blink them. Sets TAU0 to the interval timer which generates interrupts with fixed cycle.
<b>Arguments</b>	None
<b>Return Value</b>	None
taua0_led_spare	
<b>Outline</b>	Initialization of TAU0 for LED blink with fixed cycle (sample function in spare area)
<b>Header</b>	
<b>Declaration</b>	void taua0_led_spare (void)
<b>Description</b>	Sets the port connected to the LEDs to output to blink them. Sets TAU0 to the interval timer which generates interrupts with fixed cycle.
<b>Arguments</b>	None
<b>Return Value</b>	None
taua0_i0_interval_timer_isr	
<b>Outline</b>	TAU0 interval timer interrupt processing
<b>Header</b>	
<b>Declaration</b>	void taua0_i0_interval_timer_isr (void)
<b>Description</b>	Inverts P1_4 output for LED blink.
<b>Arguments</b>	None
<b>Return Value</b>	None

---

uartj0_serial_init	
<b>Outline</b>	Initialization of UARTJ0
<b>Header</b>	flash.h
<b>Declaration</b>	void uartj0_serial_init (void)
<b>Description</b>	After initializing the ports of UARTJ0, executes initial setting for UARTJ0. Then sets the interrupt level and enables the interrupts to enable UARTJ0 operation.
<b>Arguments</b>	None
<b>Return Value</b>	None

---

uartj0_serial_port_init	
<b>Outline</b>	Initialization of UARTJ0 ports
<b>Header</b>	
<b>Declaration</b>	void uartj0_serial_port_init (void)
<b>Description</b>	Initializes the ports to use P2_12 pin for reception and P2_13 for transmission in serial communication.
<b>Arguments</b>	None
<b>Return Value</b>	None

---

uartj0_serial_tx_msg	
<b>Outline</b>	UARTJ0 message transmit processing
<b>Header</b>	flash.h
<b>Declaration</b>	void uartj0_serial_tx_msg (void)
<b>Description</b>	Provides serial output of the character string specified by the argument from UARTJ0.
<b>Arguments</b>	char * msg : Transmit message character string
<b>Return Value</b>	None

---

uartj0_serial_rx_isr	
<b>Outline</b>	UARTJ0 receive interrupt processing
<b>Header</b>	
<b>Declaration</b>	void uartj0_serial_rx_isr (void)
<b>Description</b>	Specifies the received data to the argument and executes program data store processing (flash_store_serial_data function).
<b>Arguments</b>	None
<b>Return Value</b>	None

---

uartj0_serial_status_isr	
<b>Outline</b>	UARTJ0 status interrupt processing
<b>Header</b>	
<b>Declaration</b>	void uartj0_serial_status_isr (void)
<b>Description</b>	Clears the status as UARTJ0 interrupt processing.
<b>Arguments</b>	None
<b>Return Value</b>	None

---

6.7 Flowcharts

6.7.1 Startup Routine Processing

Figure 6.4 shows the Startup Routine Processing.

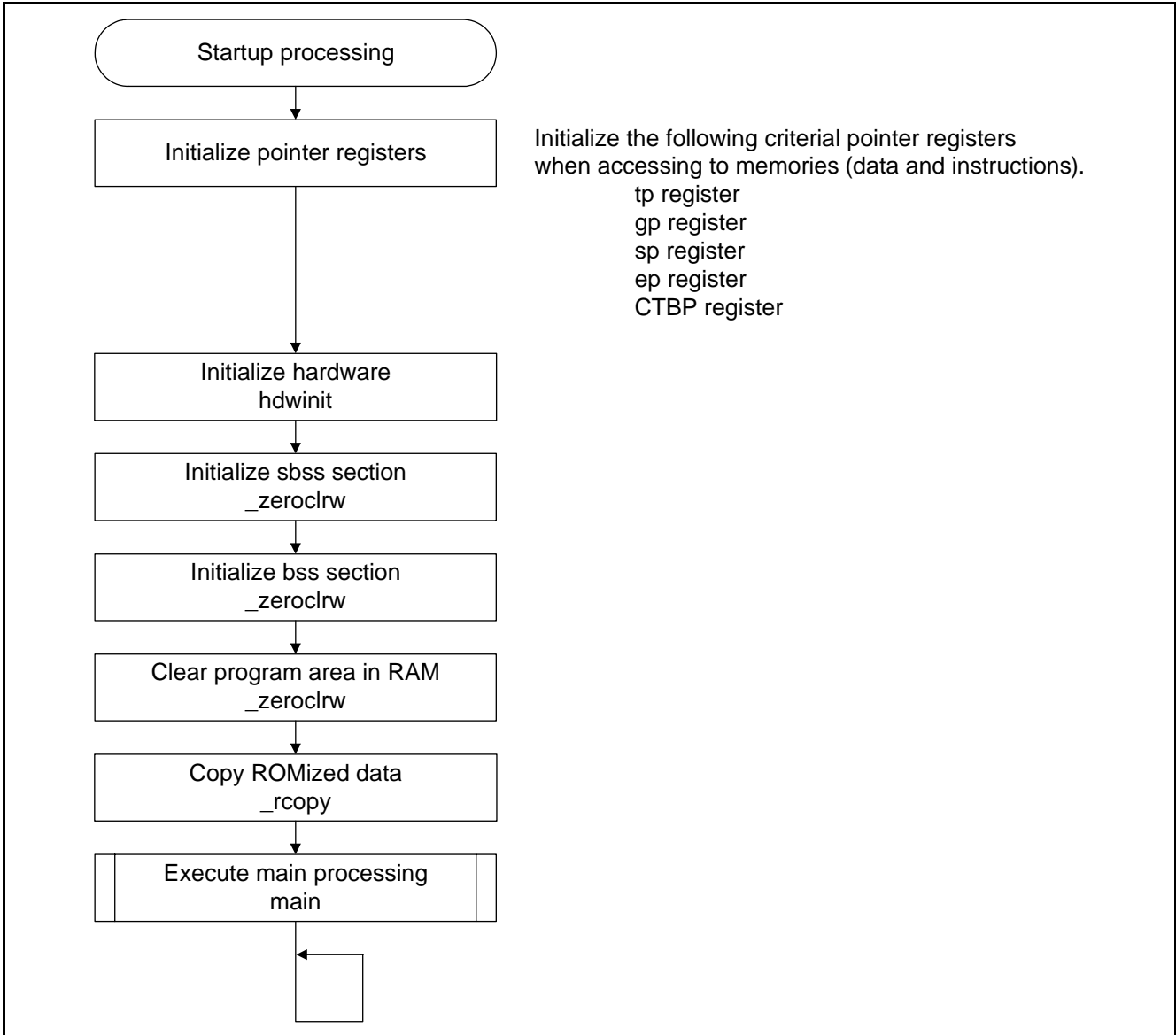


Figure 6.4 Startup Routine Processing

6.7.2 Main Processing

Figure 6.5 shows the Main Processing.

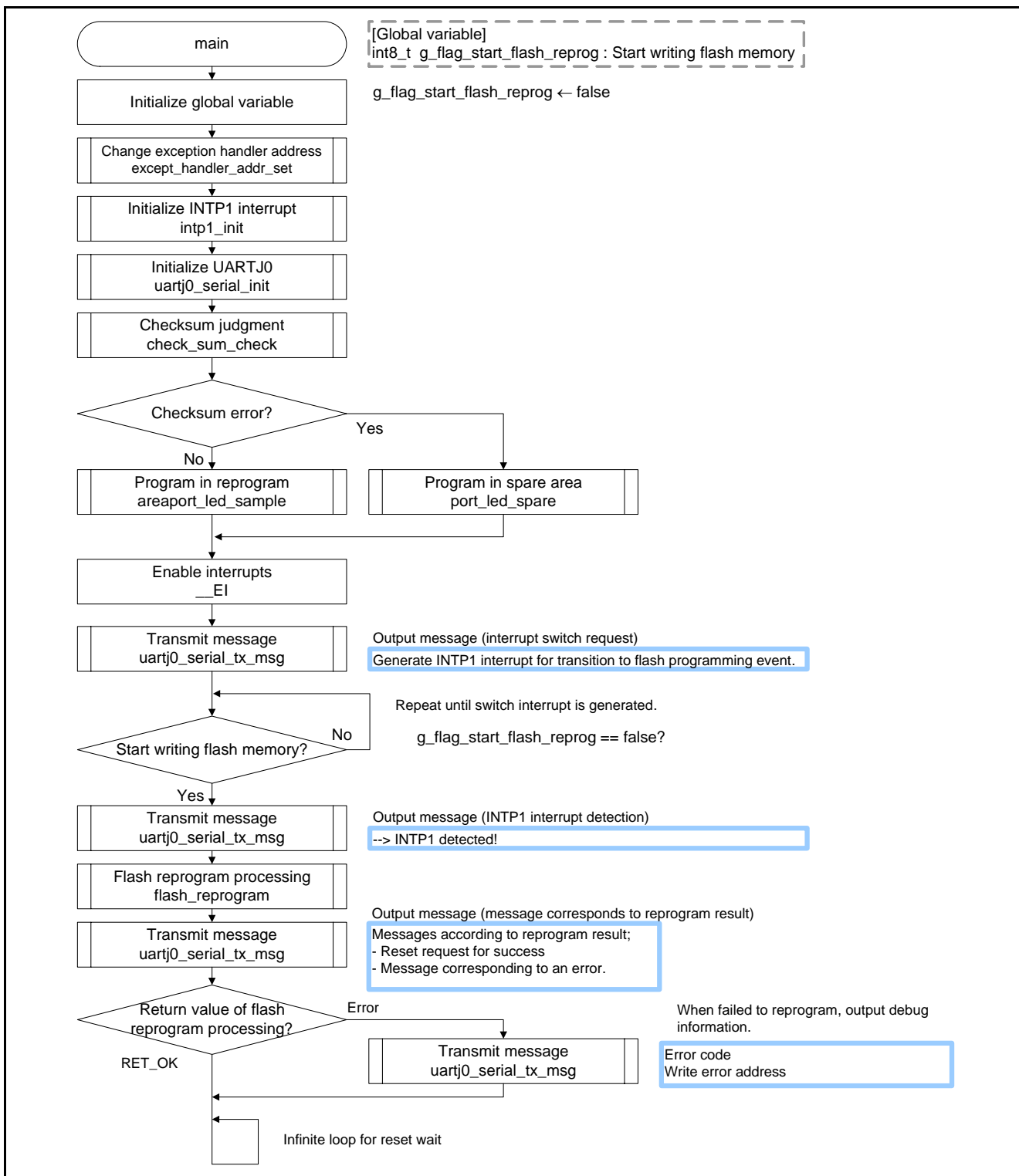


Figure 6.5 Main Processing

6.7.3 Switching Processing of Exception Handler Address

Figure 6.6 shows the Switching Processing of Exception Handler Address.

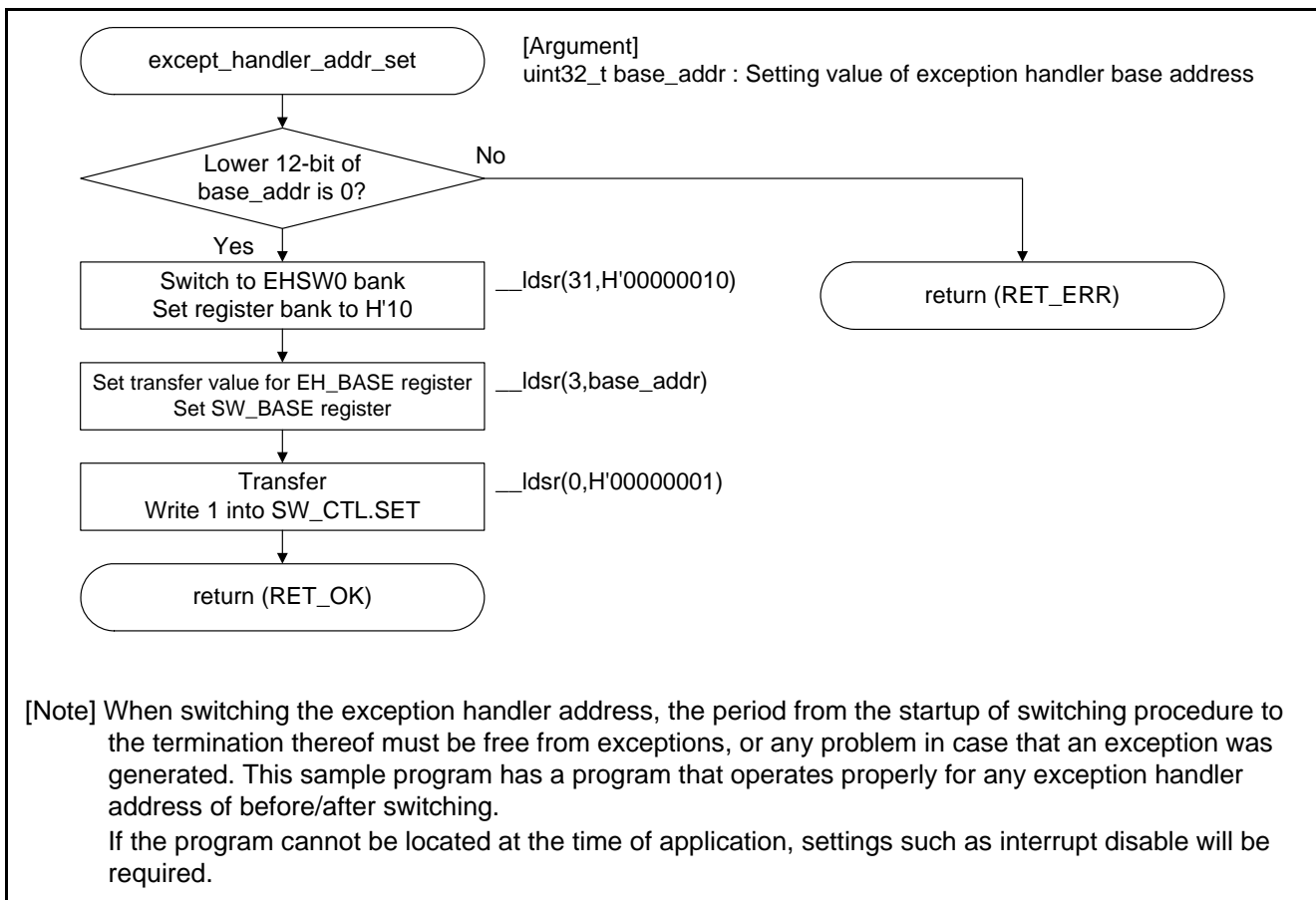


Figure 6.6 Switching Processing of Exception Handler Address

6.7.4 Checksum Judgment of Reprogram Area

Figure 6.7 shows the Checksum Judgment of Reprogram Area.

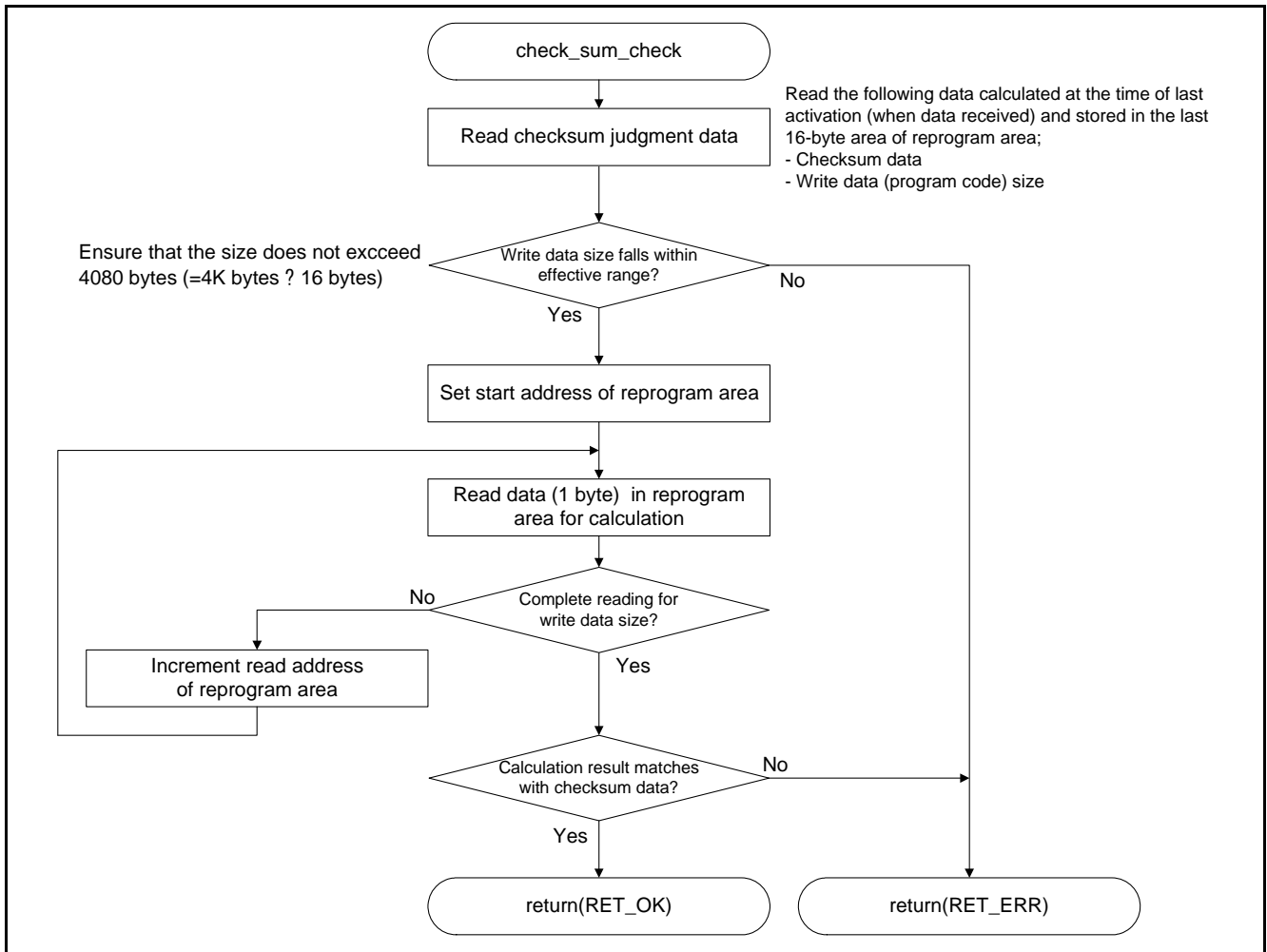


Figure 6.7 Checksum Judgment of Reprogram Area

### 6.7.5 Initialization of INTP1 Interrupt

Figure 6.8 shows the Initialization of INTP1 Interrupt.

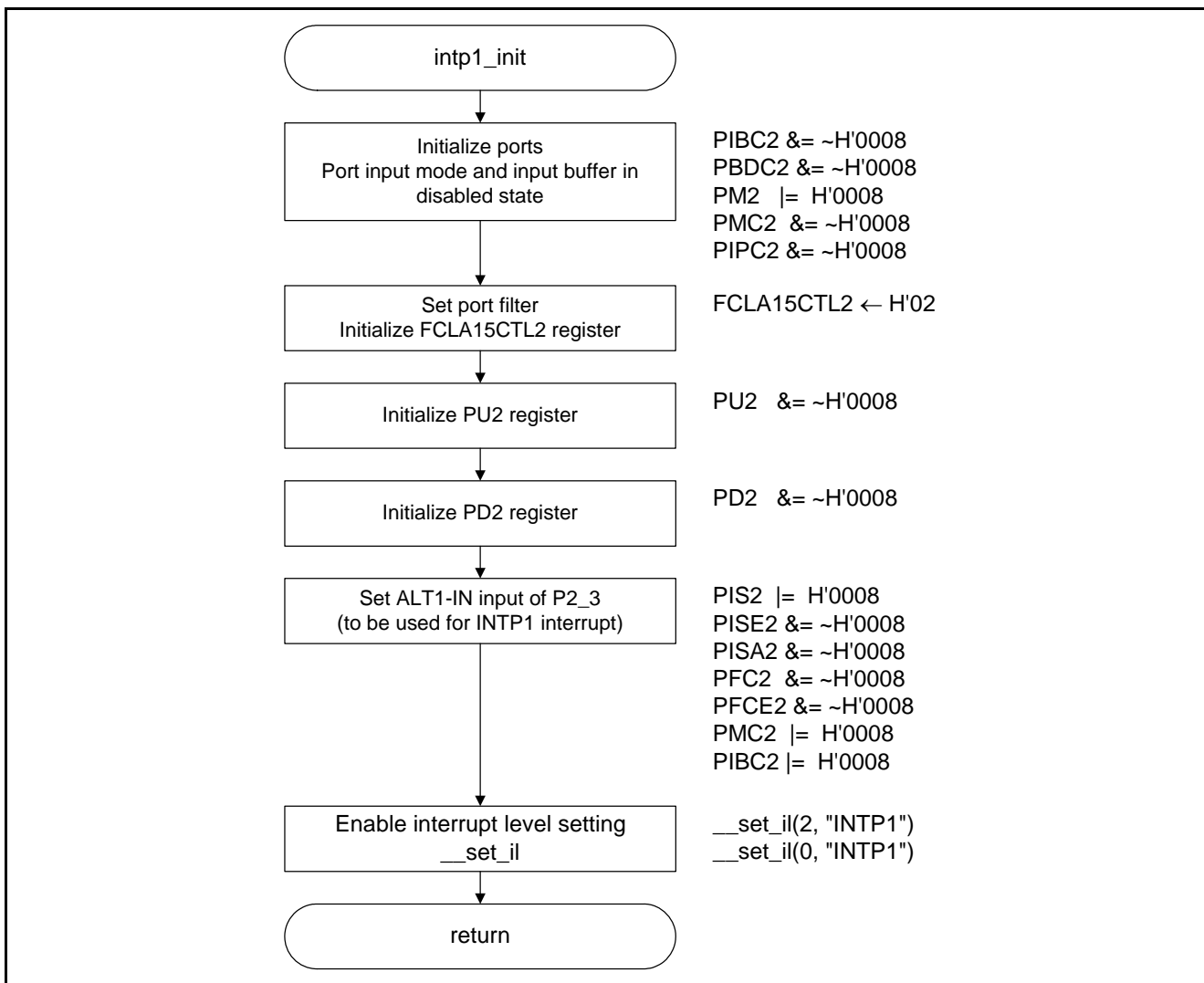


Figure 6.8 Initialization of INTP1 Interrupt

6.7.6 INPT1 Interrupt Processing

Figure 6.9 shows the INTP1 Interrupt Processing.

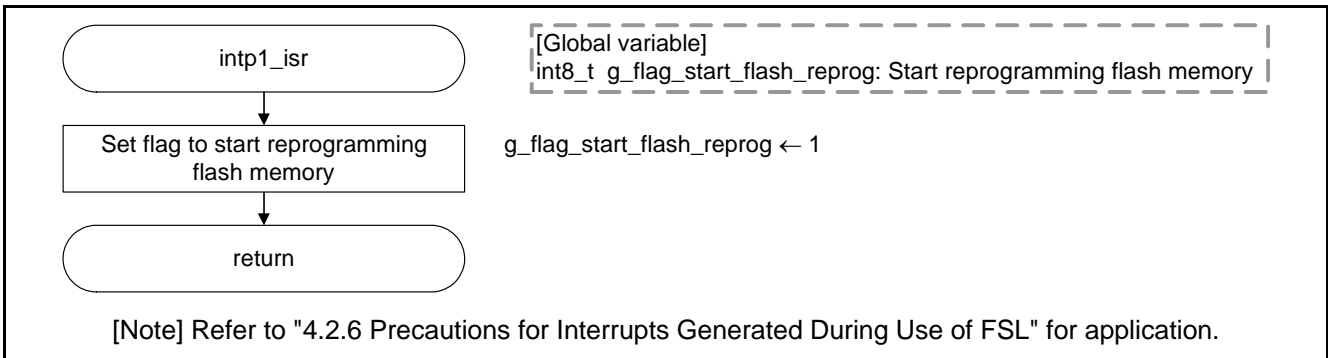


Figure 6.9 INTP1 Interrupt Processing



6.7.7 Flash Reprogram Processing

Figure 6.10 and Figure 6.11 show the Flash Reprogram Processing.

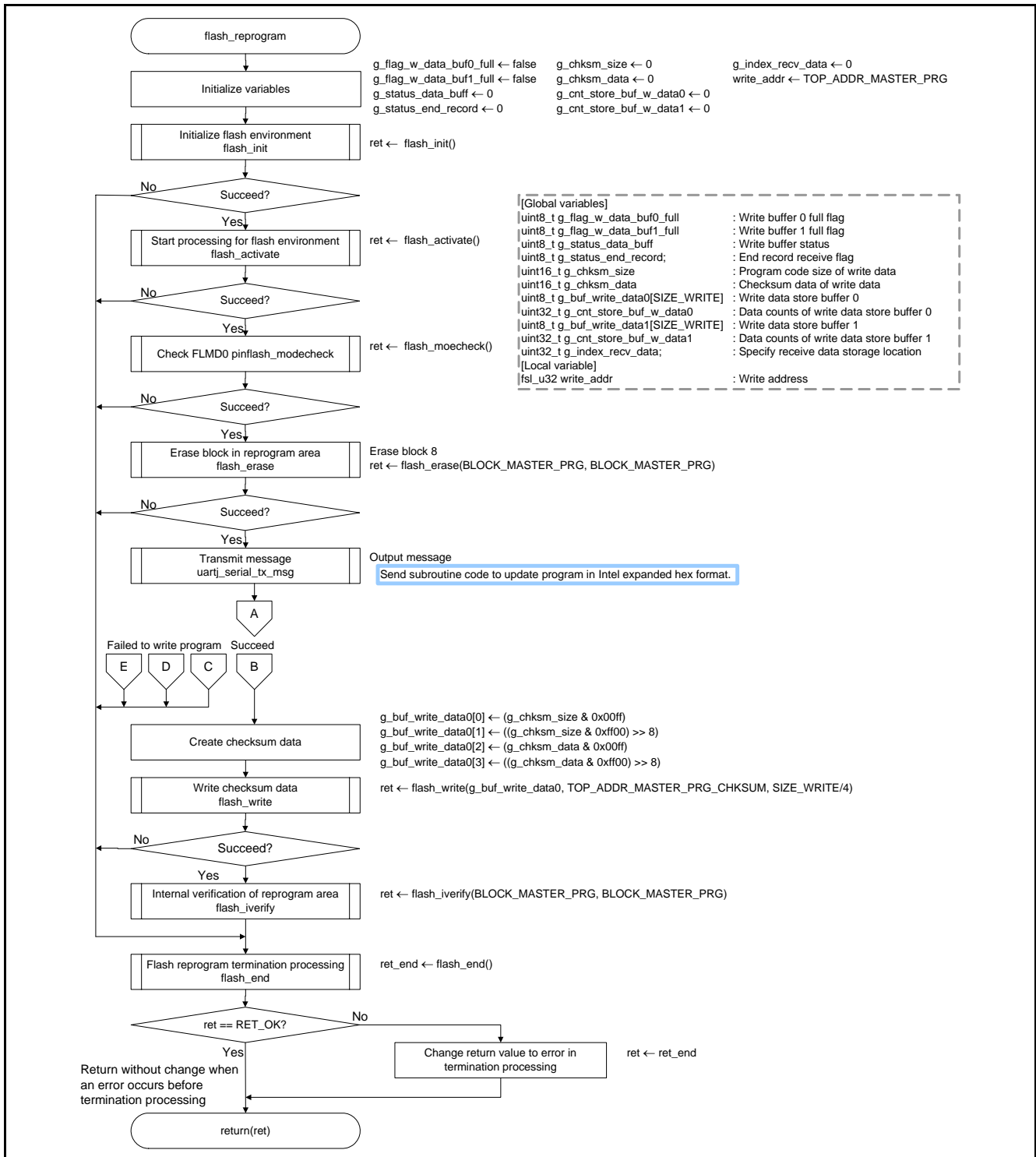


Figure 6.10 Flash Reprogram Processing (1/2)

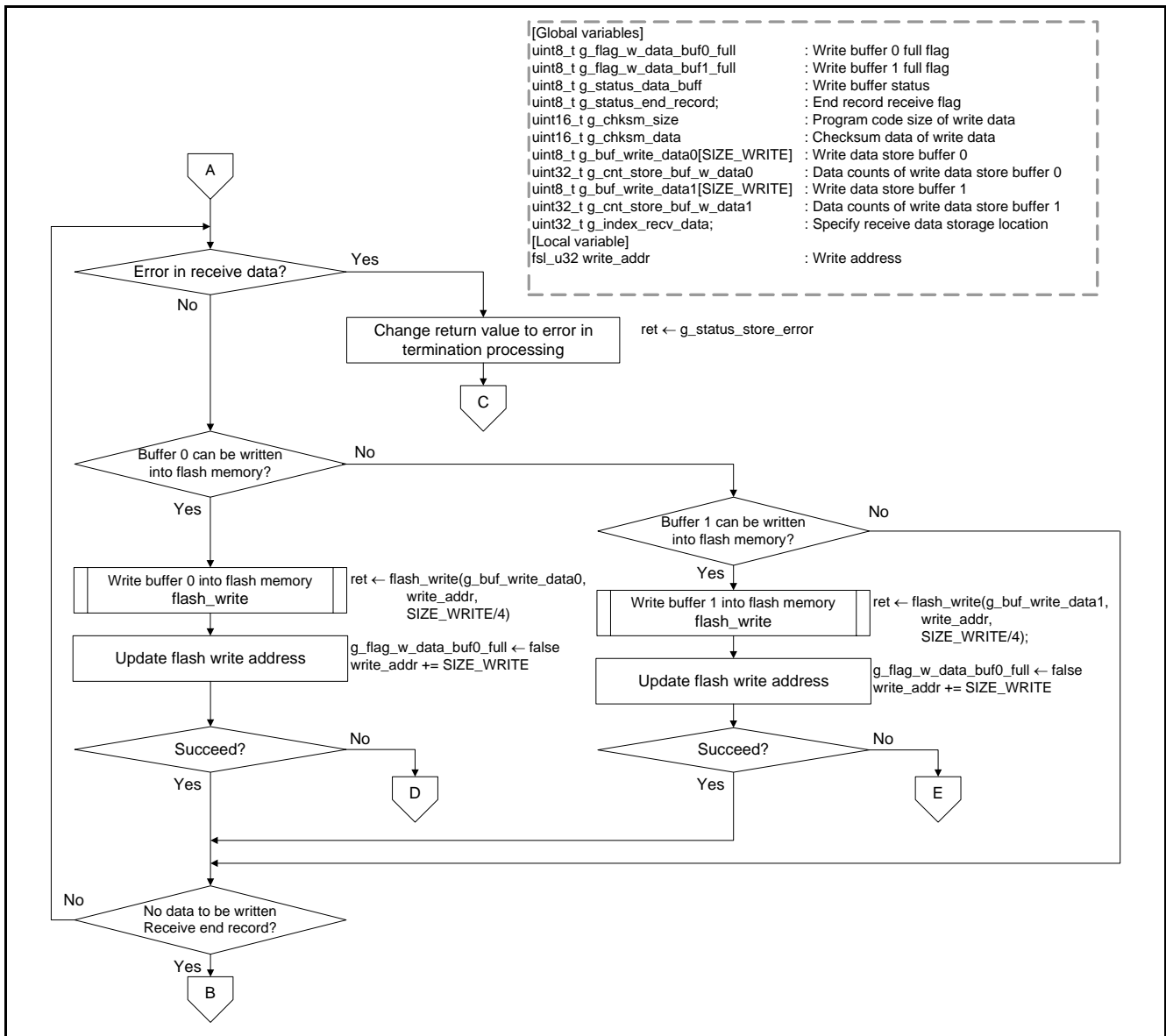


Figure 6.11 Flash Reprogram Processing (2/2)

### 6.7.8 Initialization of Flash Environment

Figure 6.12 shows the Initialization of Flash Environment.

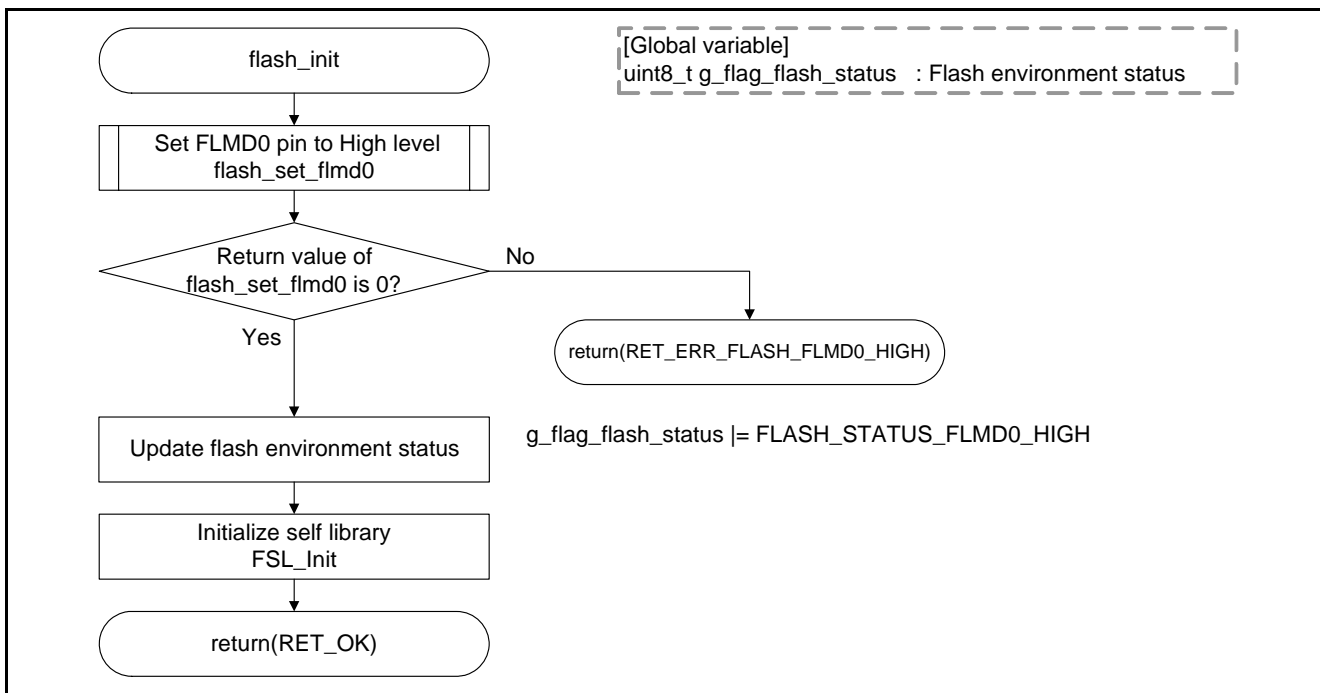


Figure 6.12 Initialization of Flash Environment

6.7.9 Start Processing of Flash Environment

Figure 6.13 shows the Start Processing of Flash Environment.

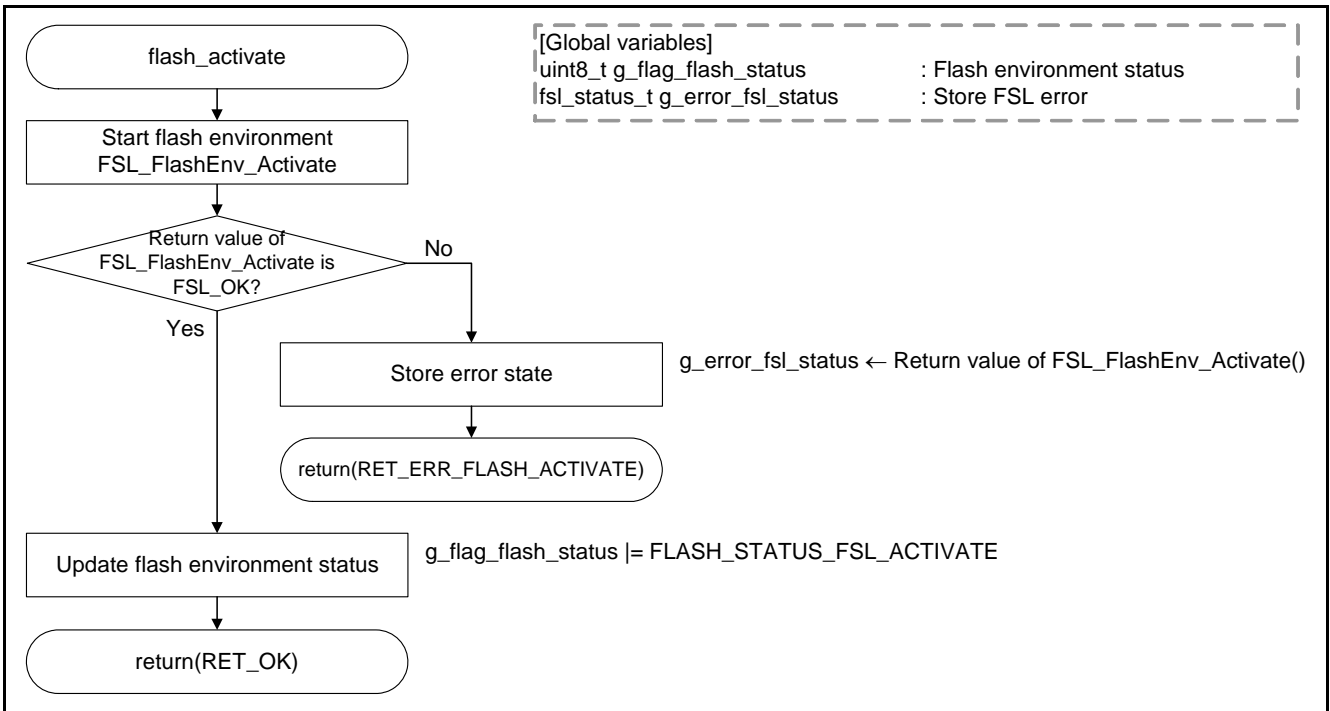


Figure 6.13 Start Processing of Flash Environment

6.7.10 Checking Processing of FLMD0 Pin Using FSL

Figure 6.14 shows the Checking Processing of FLMD0 Pin Using FSL.

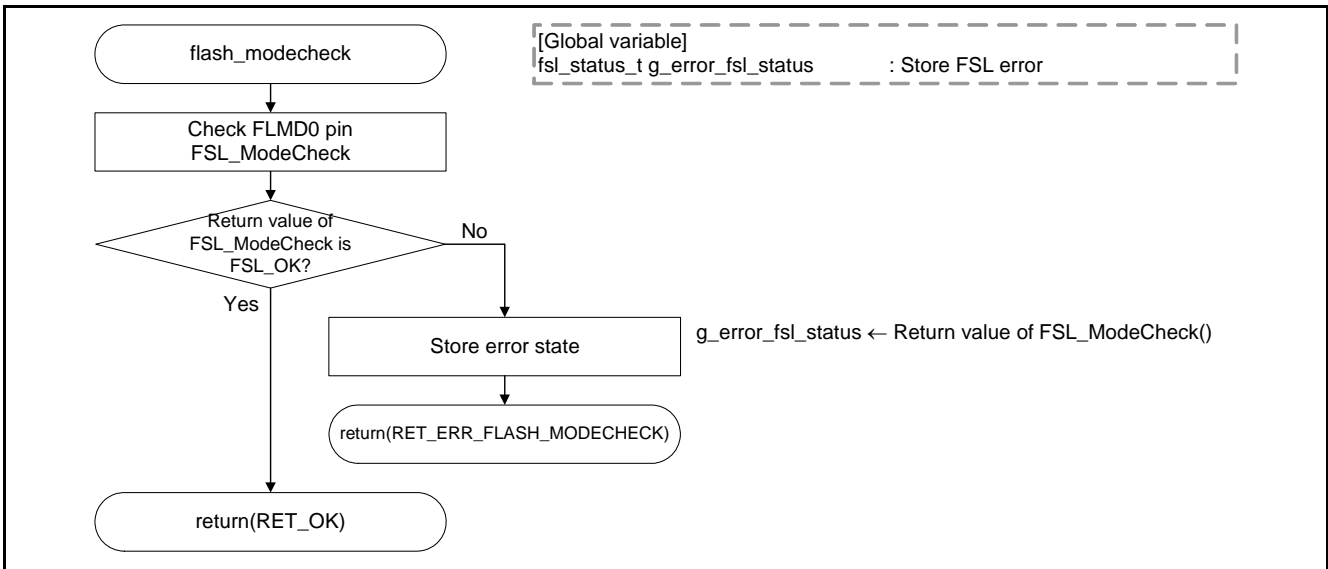


Figure 6.14 Checking Processing of FLMD0 Pin Using FSL

6.7.11 Erase Processing of Specified Block

Figure 6.15 shows the Erase Processing of Specified Block.

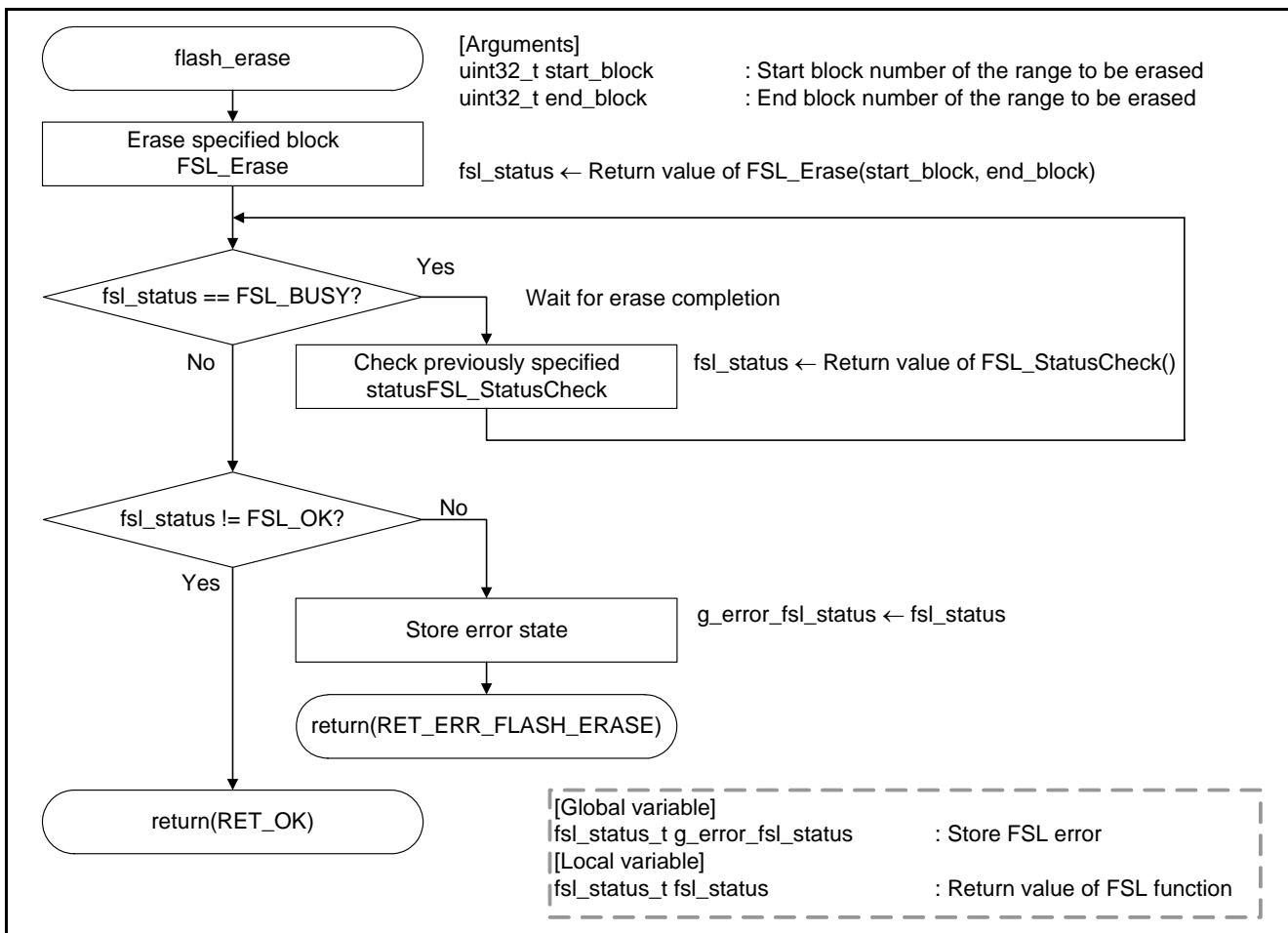


Figure 6.15 Erase Processing of Specified Block

6.7.12 Write Processing from Specified Address

Figure 6.16 shows the Write Processing from Specified Address.

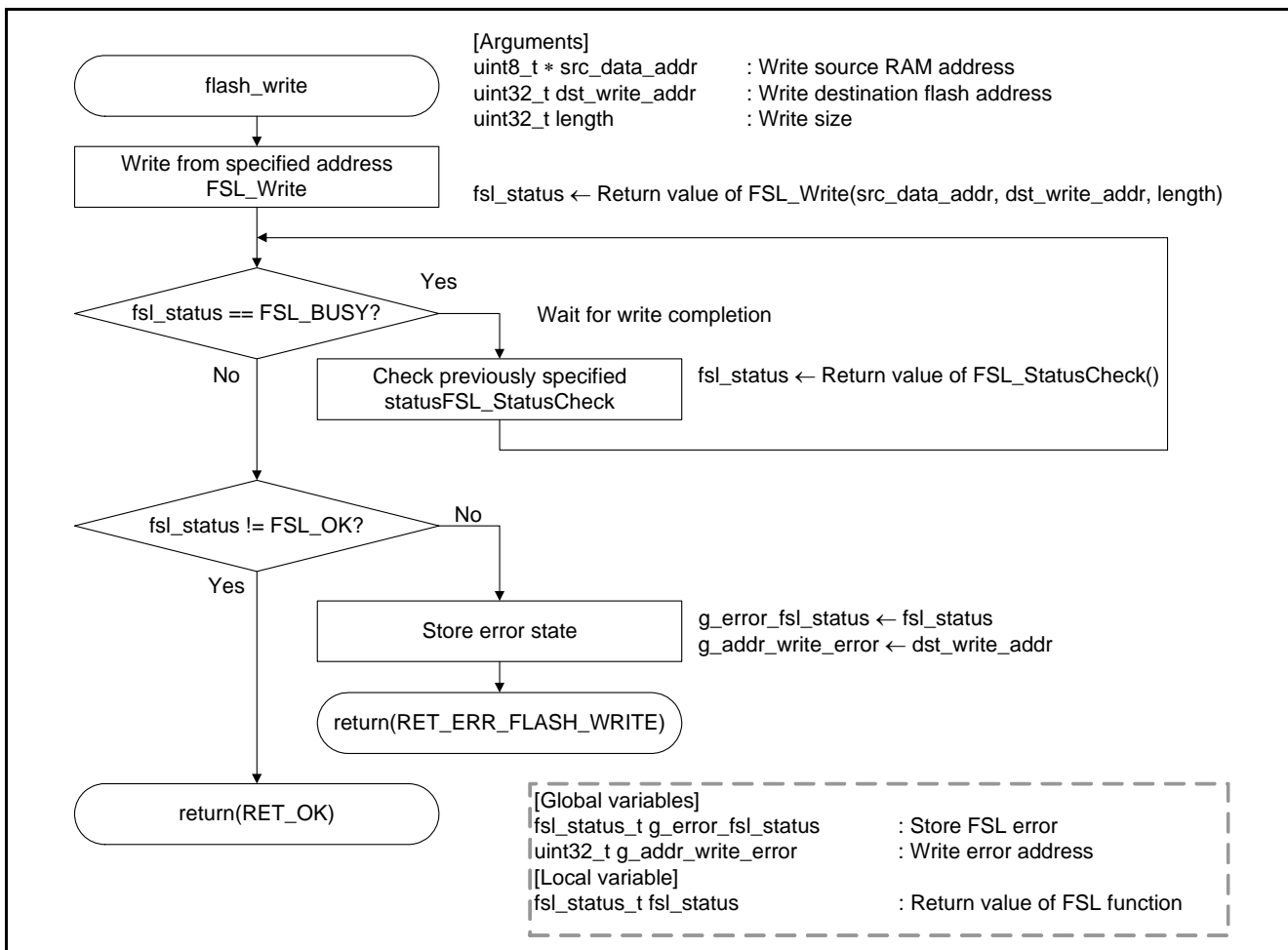


Figure 6.16 Write Processing from Specified Address

6.7.13 Internal Verification of Specified Block

Figure 6.17 shows the Internal Verification of Specified Block.

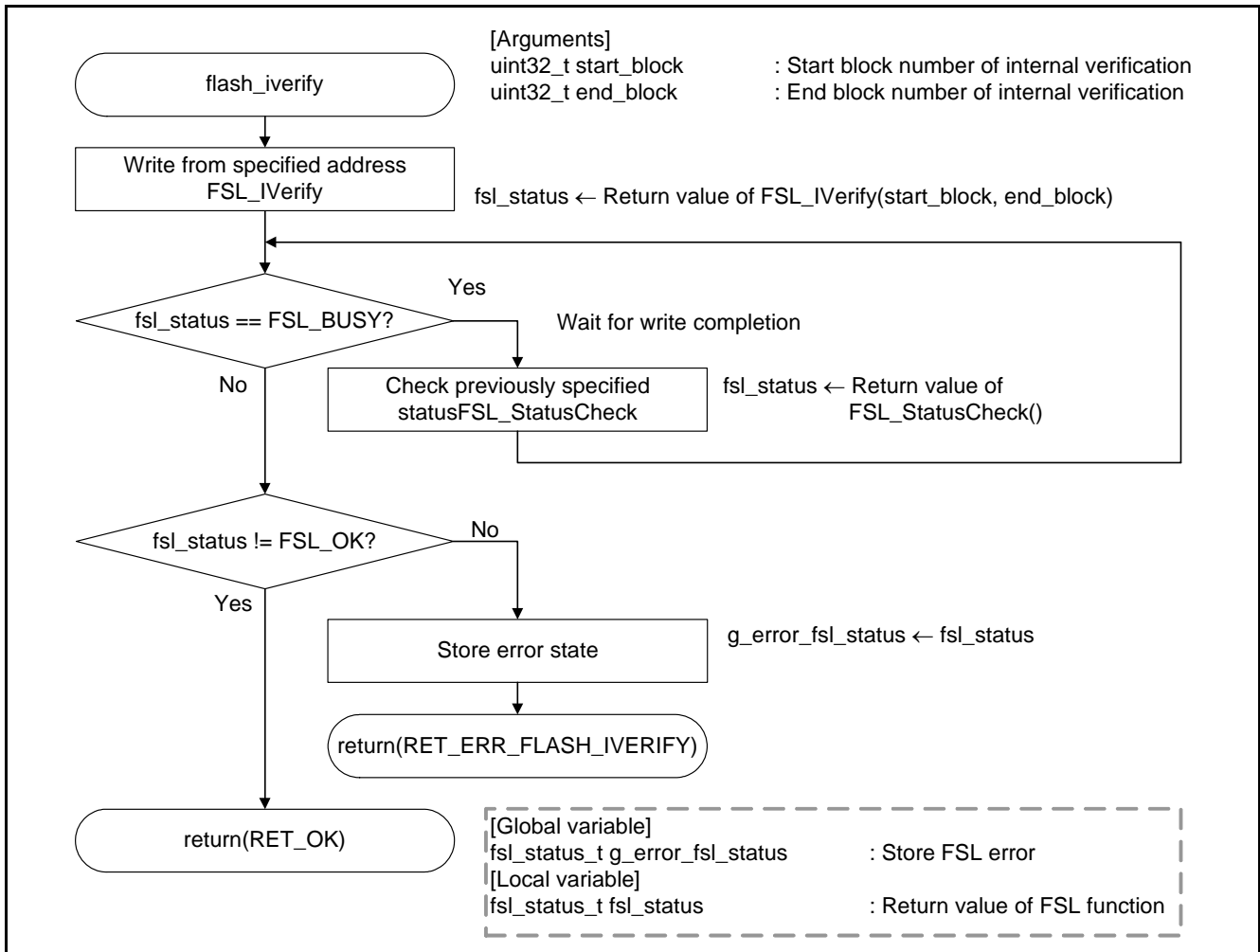


Figure 6.17 Internal Verification of Specified Block



6.7.14 Termination Processing of Flash Environment

Figure 6.18 shows the Termination Processing of Flash Environment.

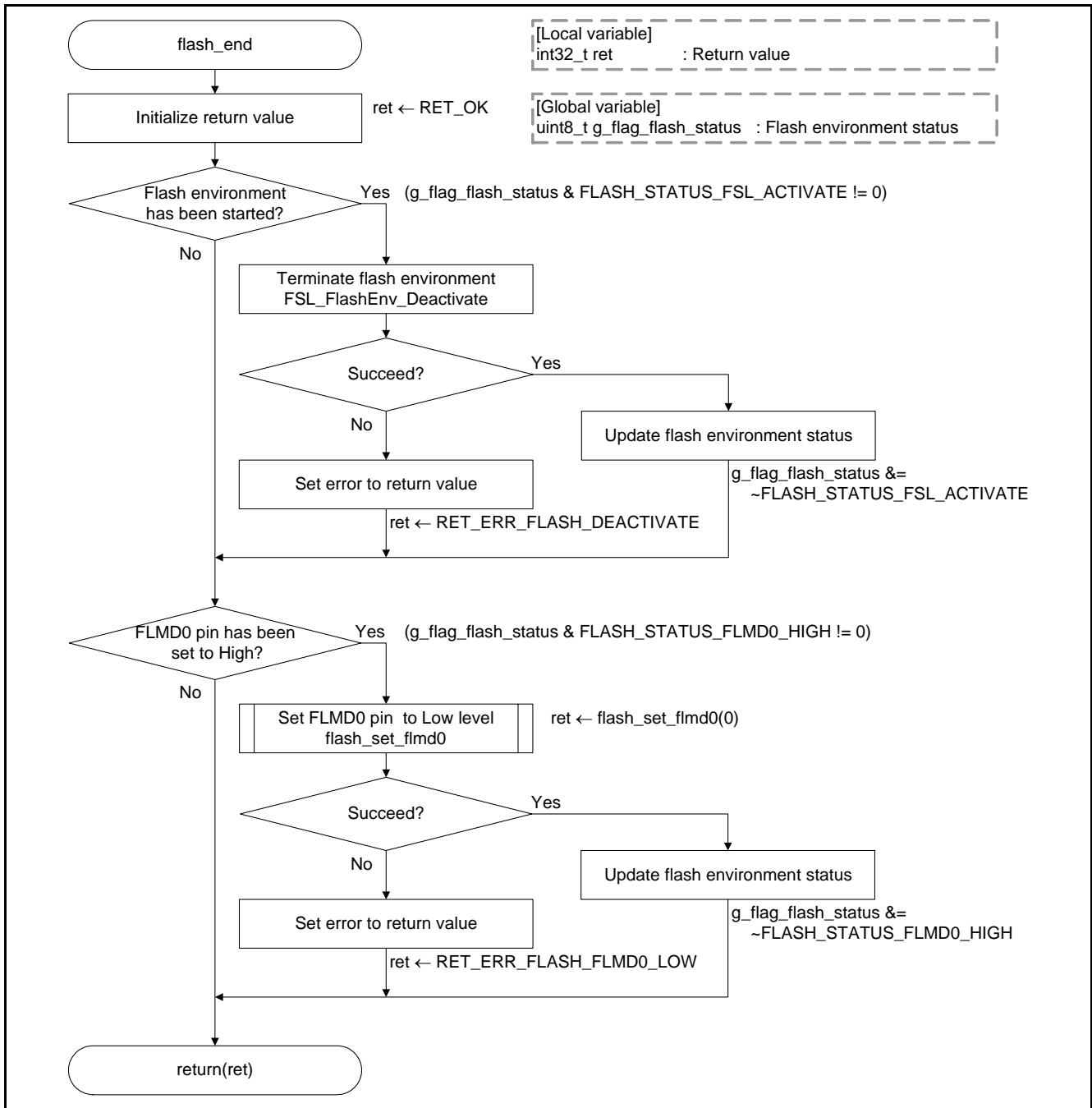


Figure 6.18 Termination Processing of Flash Environment

6.7.15 Setting for FLMD0 Pin Level

Figure 6.19 shows the Setting for FLMD0 Pin Level.

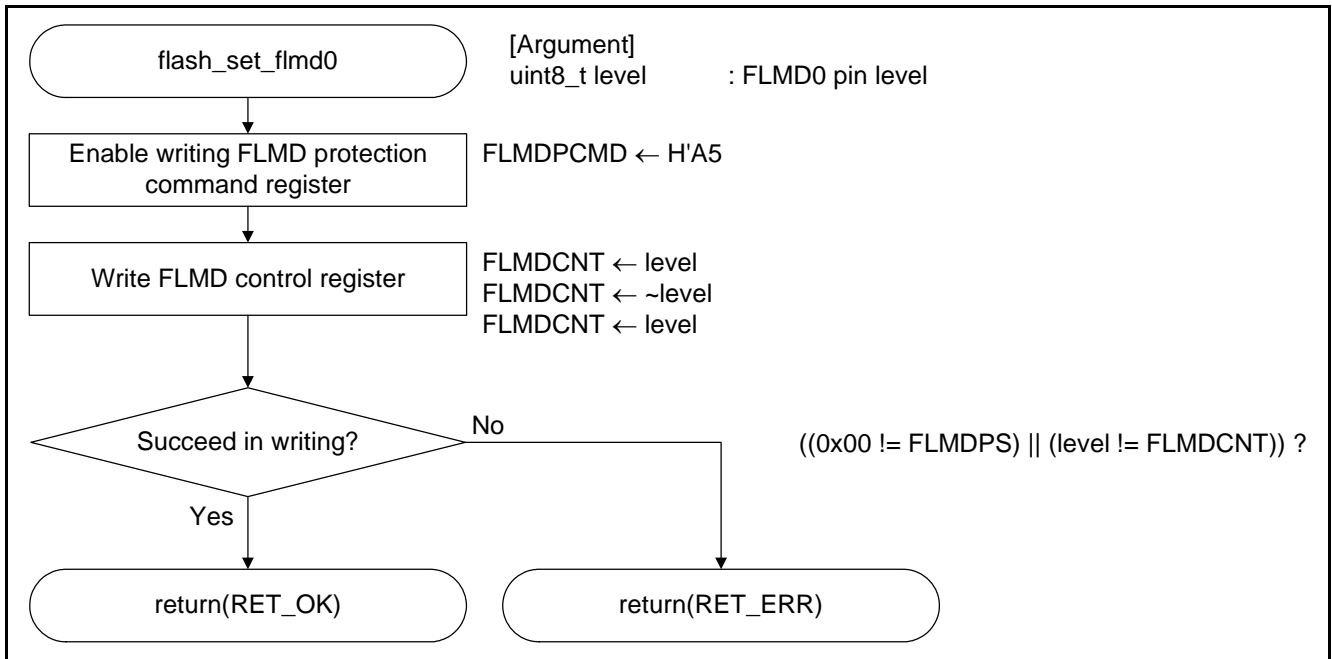


Figure 6.19 Setting for FLMD0 Pin Level

6.7.16 Store Processing for Receive Data

Figure 6.20 and Figure 6.21 show the Store Processing for Receive Data.

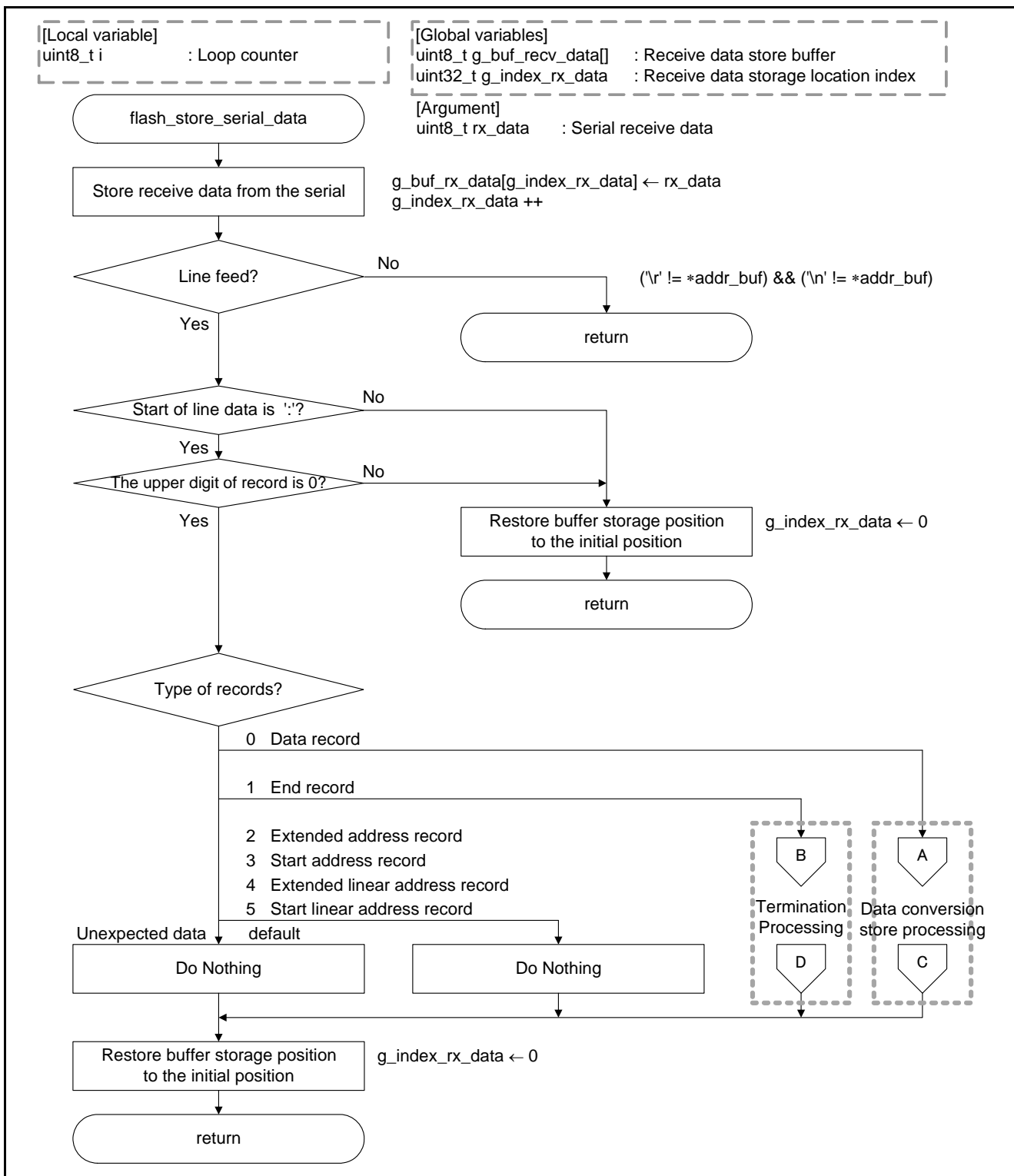


Figure 6.20 Store Processing for Receive Data (1/2)

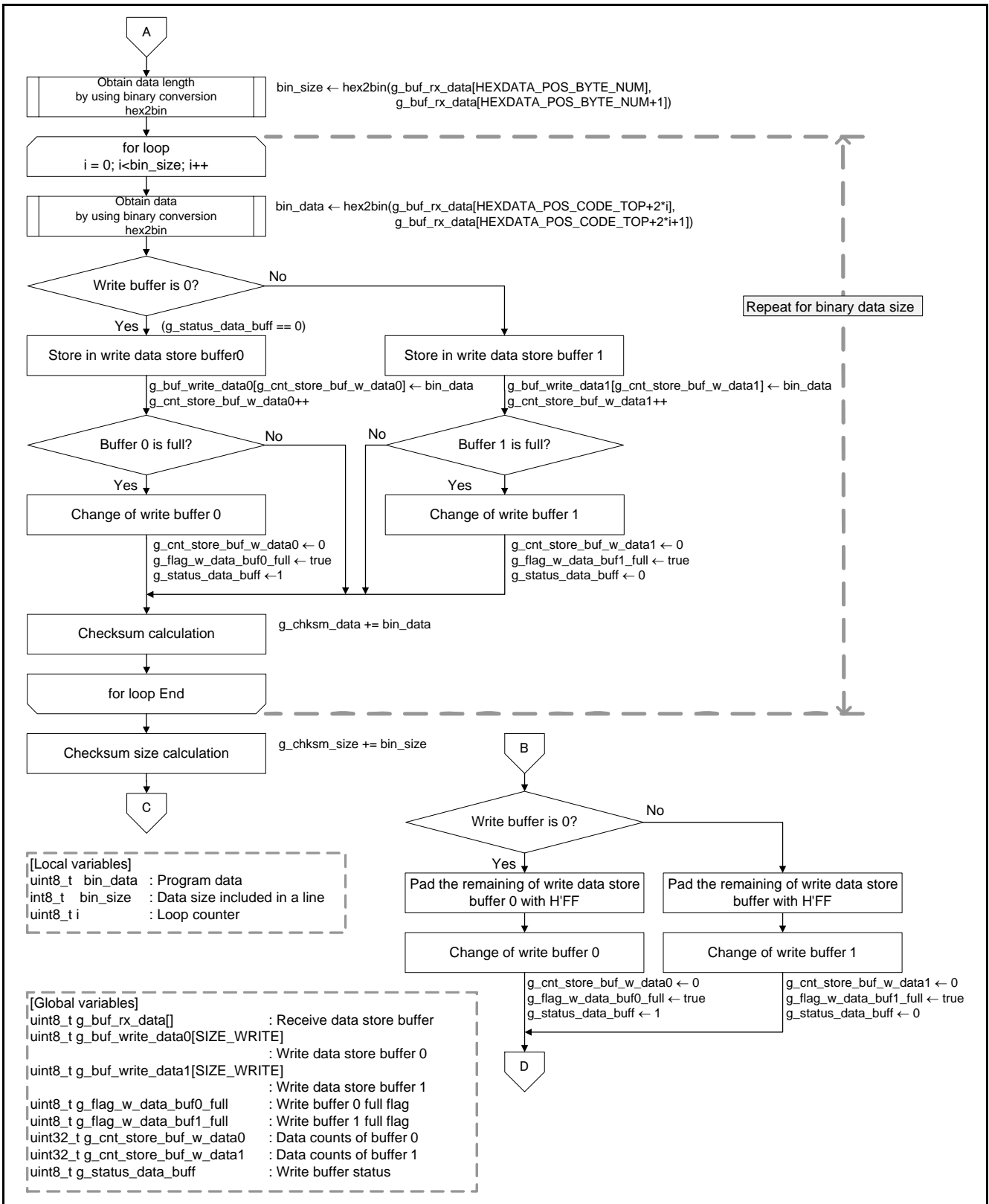


Figure 6.21 Store Processing for Receive Data (2/2)

6.7.17 Text Binary Conversion Processing

Figure 6.22 shows the Text Binary Conversion Processing.

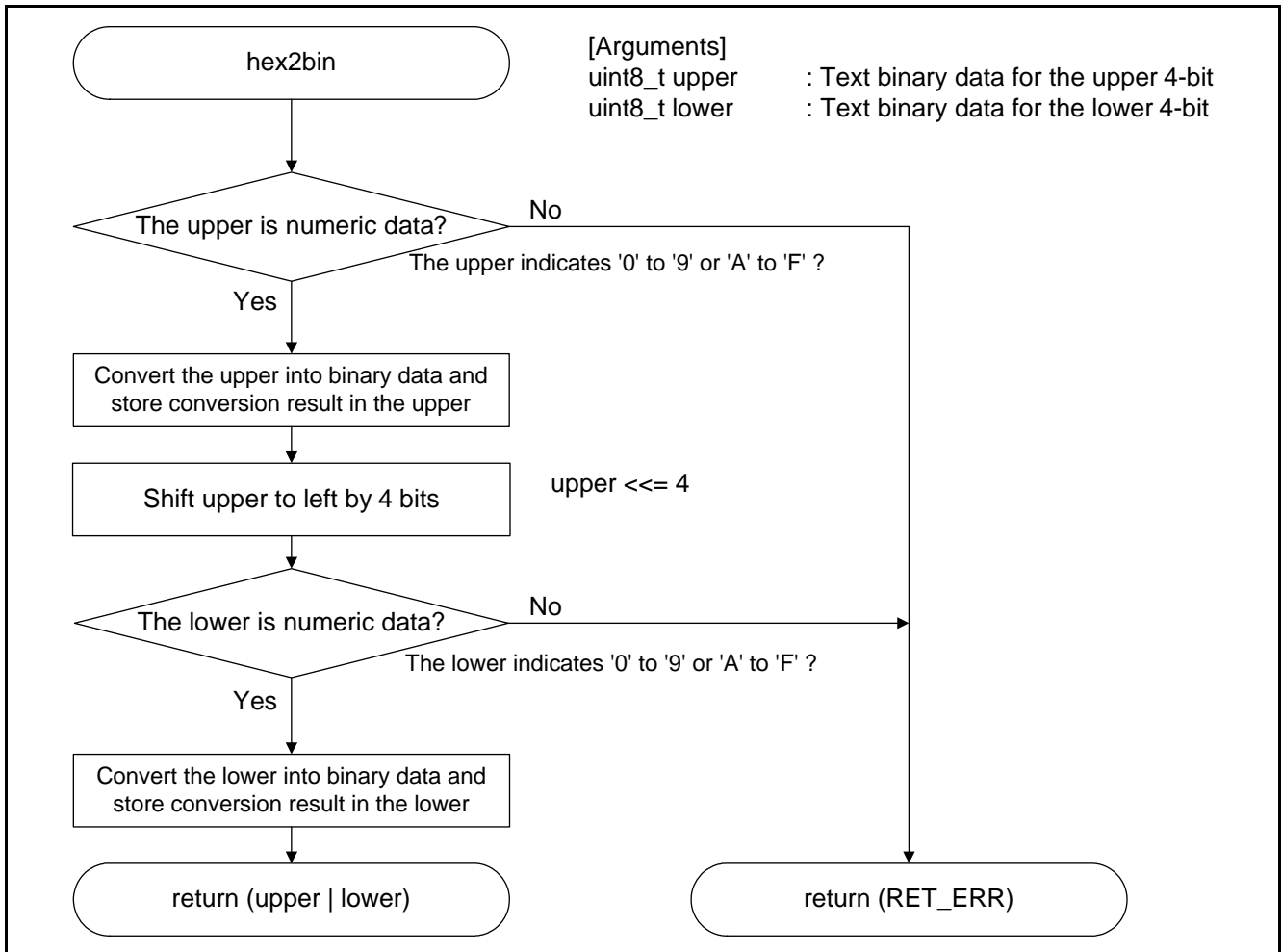
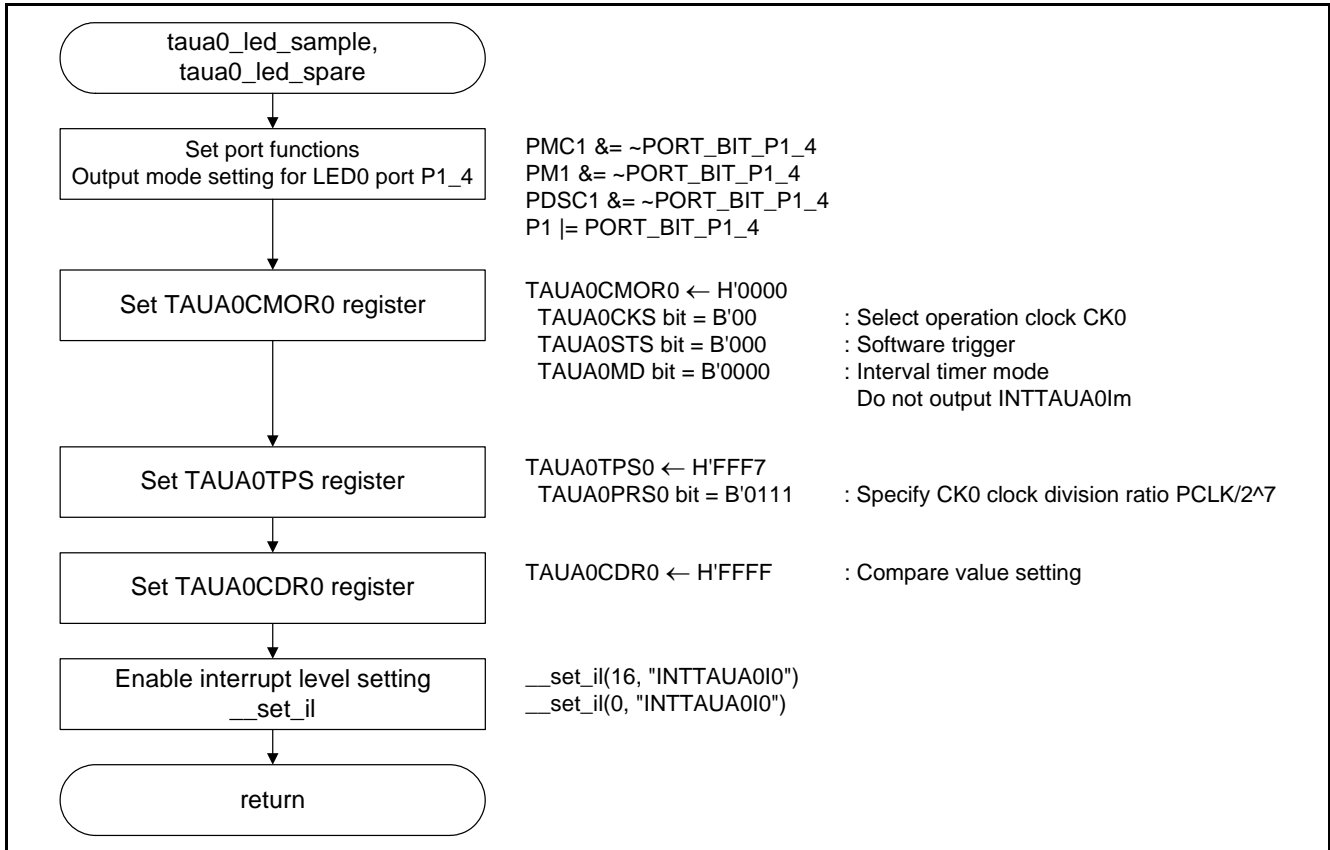


Figure 6.22 Text Binary Conversion Processing

**6.7.18 TAU0 Initialization for LED Blink with Fixed Cycle (Sample Function in Reprogram Area and Spare Area)**

Figure 6.23 shows the TAU0 Initialization for LED blink with Fixed Cycle (Sample Function in Reprogram Area and Spare Area).



**Figure 6.23 TAU0 Initialization for LED blink with Fixed Cycle (Sample Function in Reprogram Area and Spare Area)**

### 6.7.19 TAU0 Interval Timer Interrupt Processing

Figure 6.24 shows the TAU0 Interval Timer Interrupt Processing.

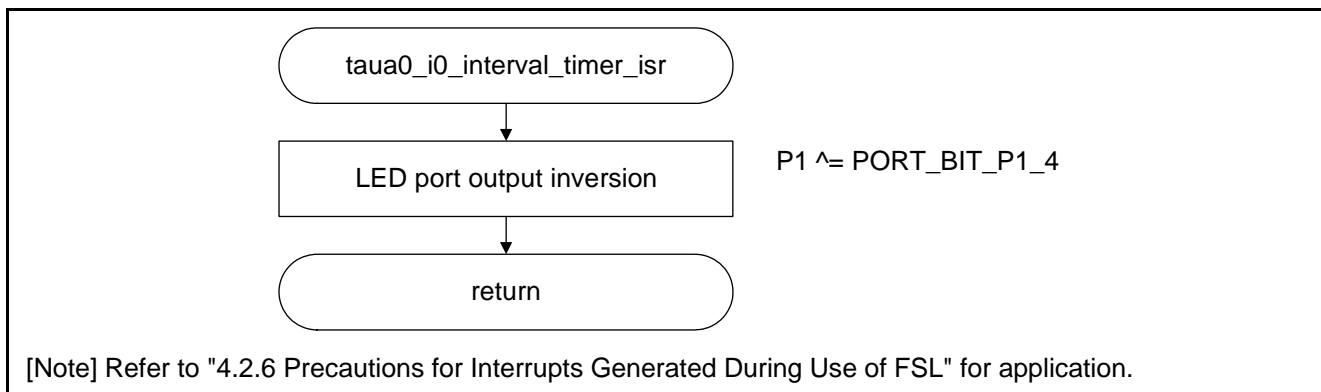


Figure 6.24 TAU0 Interval Timer Interrupt Processing

6.7.20 Initialization of UARTJ0

Figure 6.25 shows the Initialization of UARTJ0.

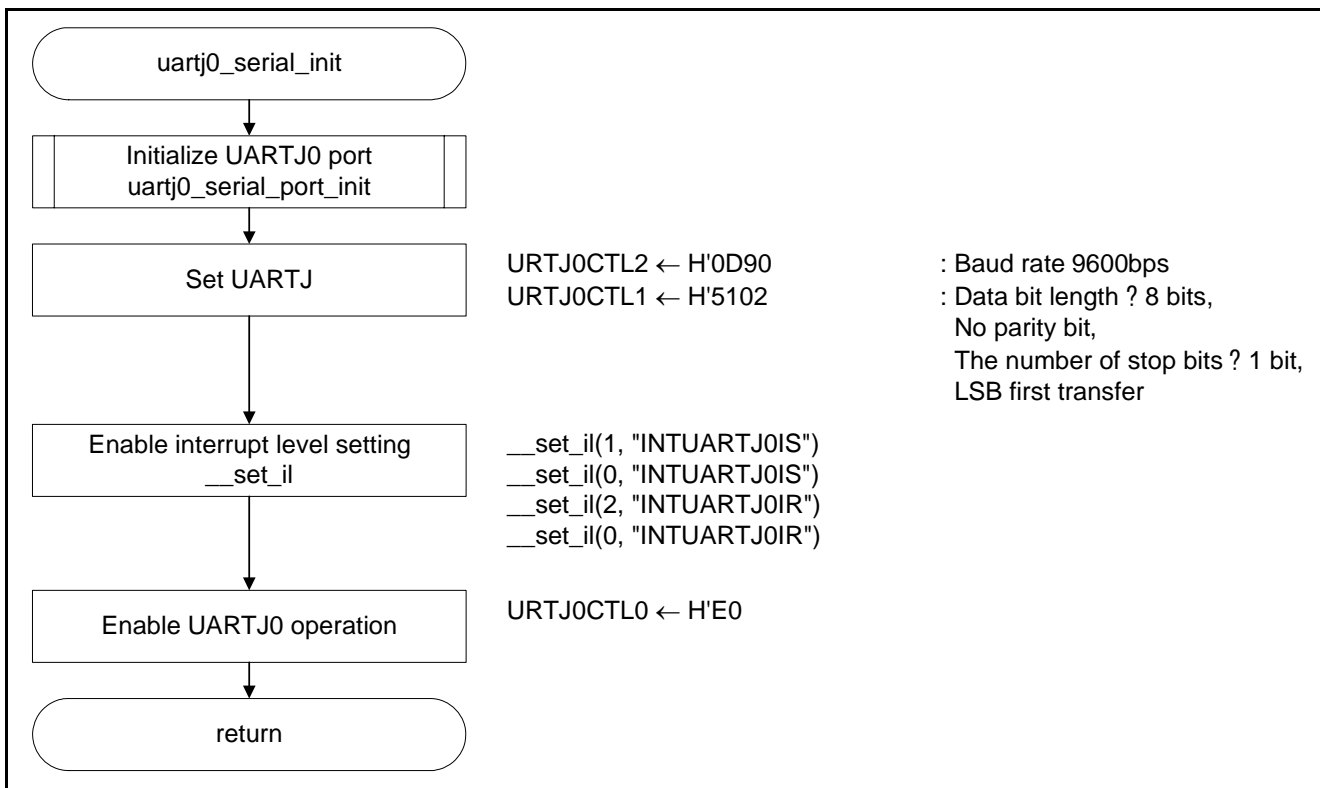


Figure 6.25 Initialization of UARTJ0



6.7.21 Initialization of UARTJ0 Ports

Figure 6.26 shows the Initialization of UARTJ0 Ports.

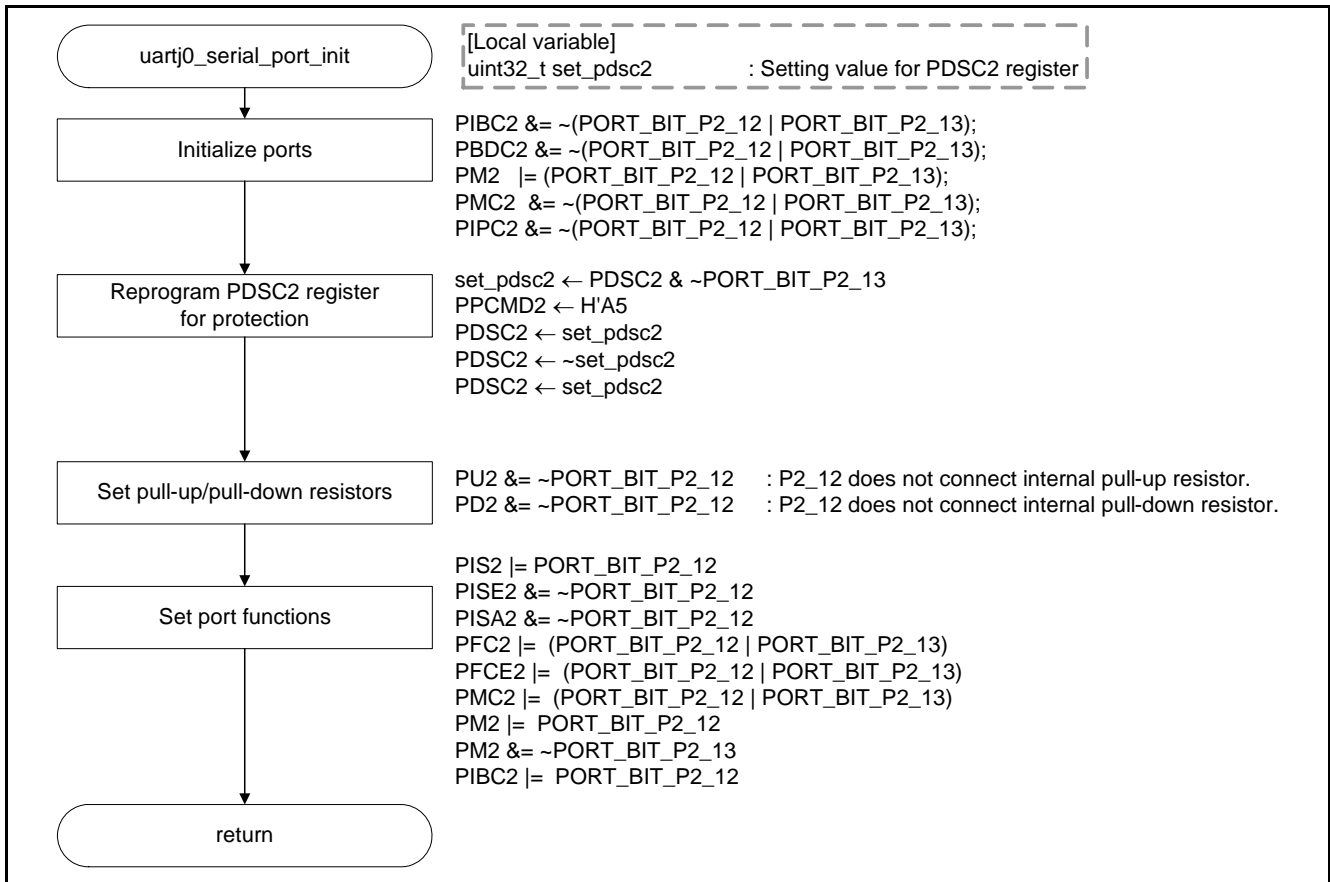


Figure 6.26 Initialization of UARTJ0 Ports

6.7.22 UARTJ0 Message Transmit Processing

Figure 6.27 shows the UARTJ0 Message Transmit Processing.

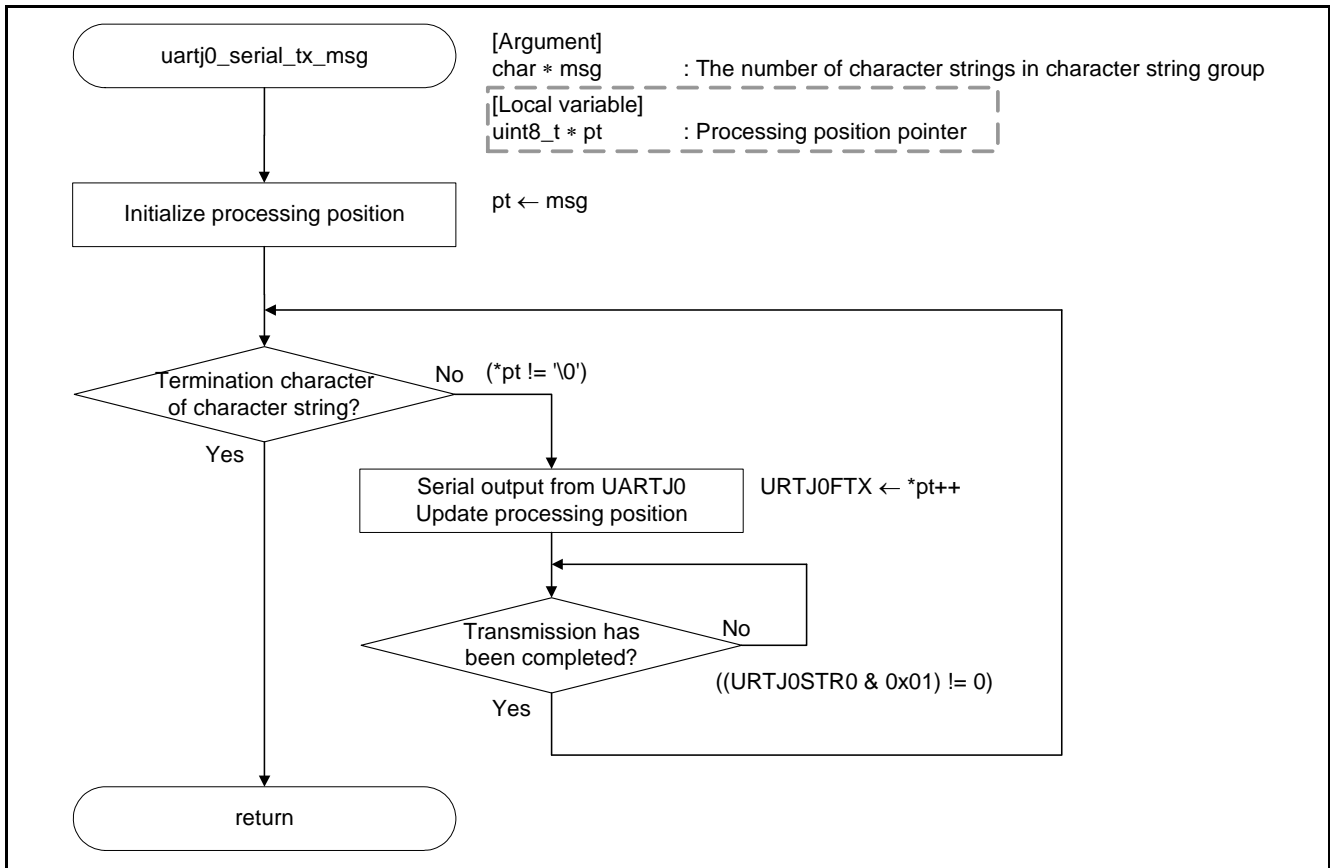


Figure 6.27 UARTJ0 Message Transmit Processing

6.7.23 UARTJ0 Receive Interrupt Processing

Figure 6.28 shows the UARTJ0 Receive Interrupt Processing.

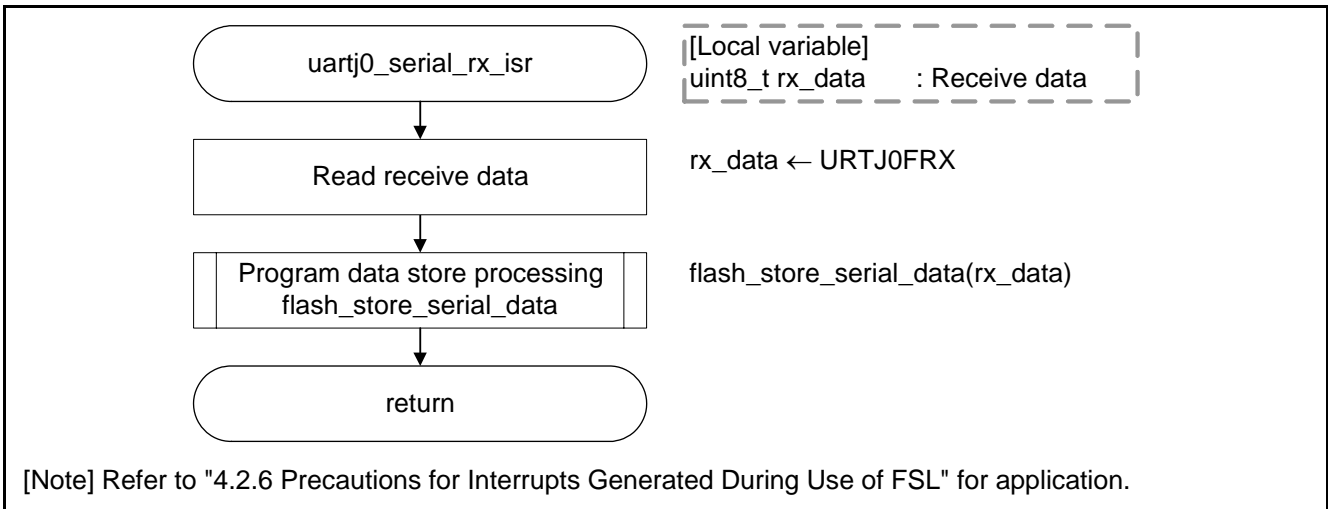
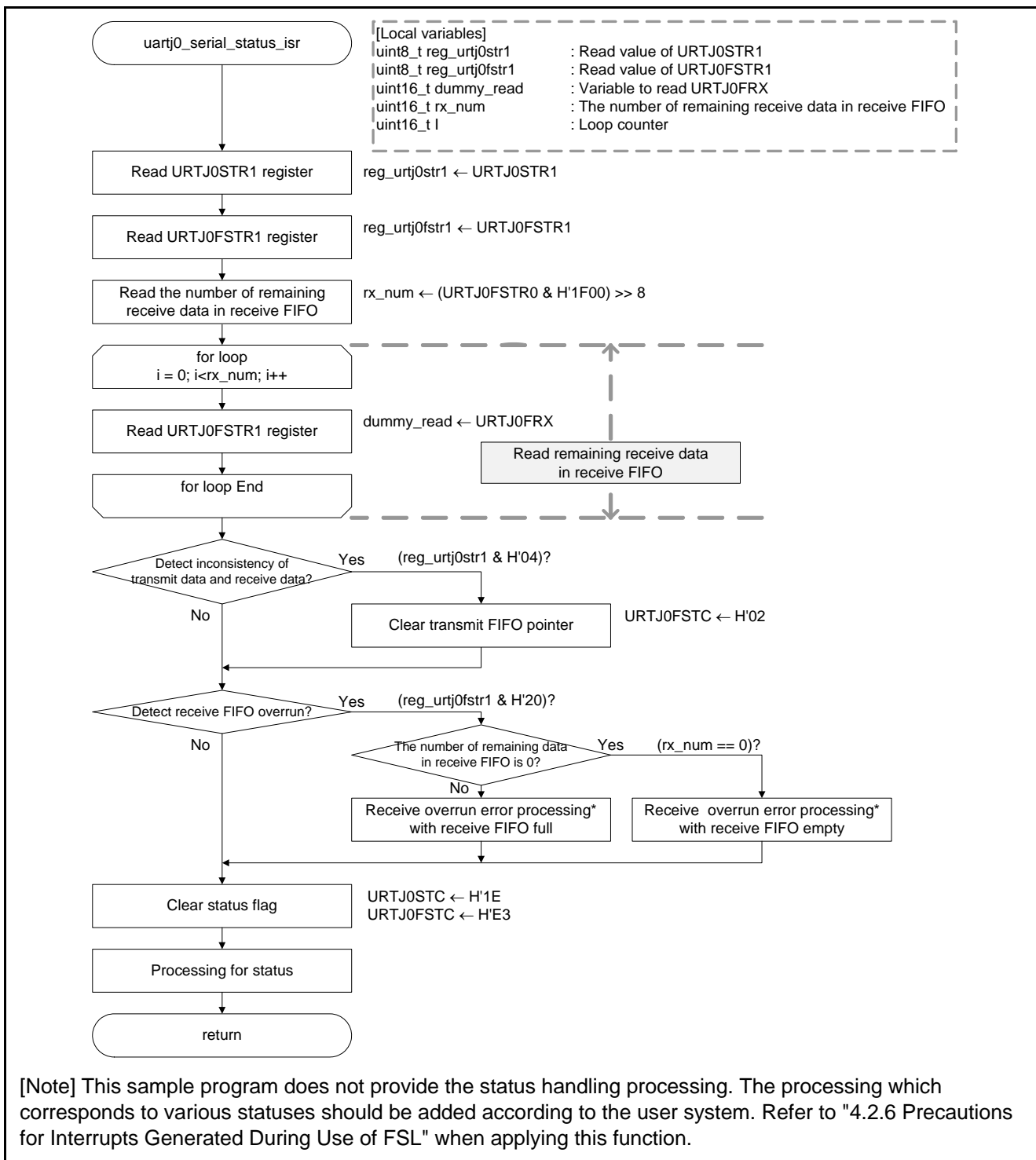


Figure 6.28 UARTJ0 Receive Interrupt Processing

6.7.24 UARTJ0 Status Interrupt Processing

Figure 6.29 shows the UARTJ0 Status Interrupt Processing.



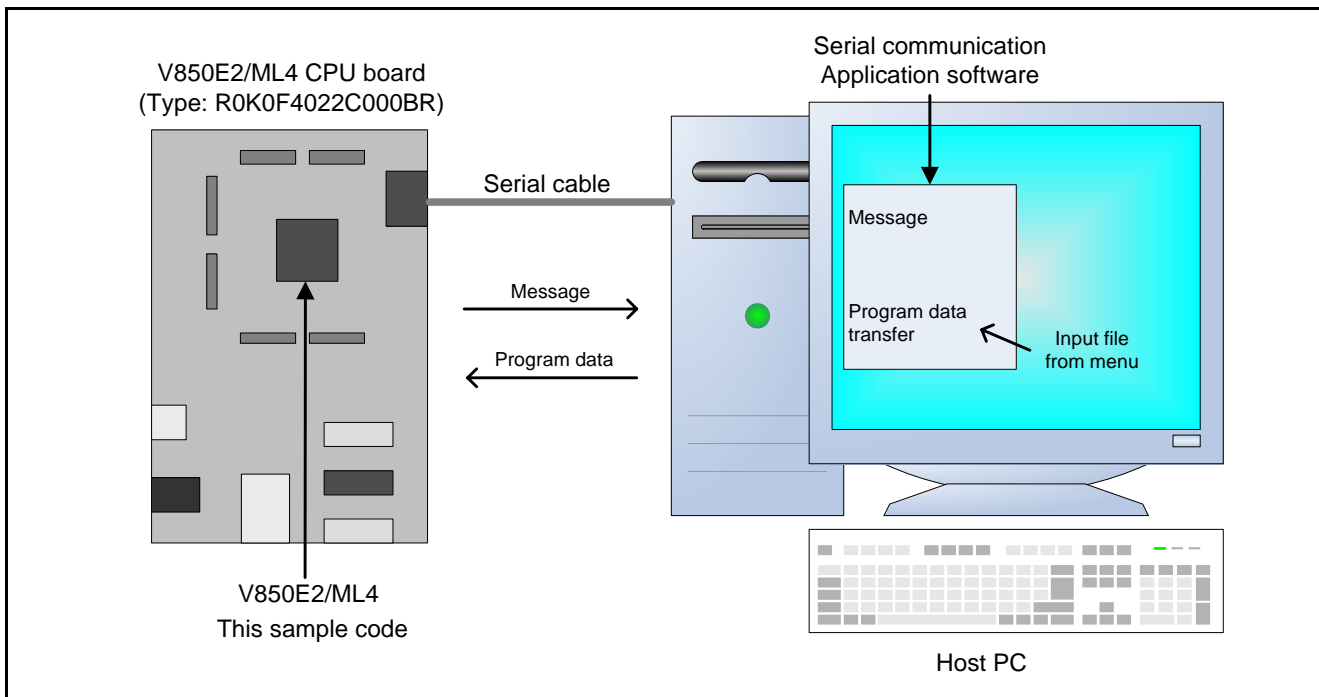
[Note] This sample program does not provide the status handling processing. The processing which corresponds to various statuses should be added according to the user system. Refer to "4.2.6 Precautions for Interrupts Generated During Use of FSL" when applying this function.

Figure 6.29 UARTJ0 Status Interrupt Processing

### 7. Operation Overview

In this sample program, the updating program is transmitted by using the serial communication host device. This chapter describes an example of controlling the data transmission using the PC as a serial communication host device.

Figure 7.1 shows the Hardware Configuration Example for Sample Code.



**Figure 7.1 Hardware Configuration Example for Sample Code**

JP1 for signal selection of the CPU board should be switched to 2-3 to use the INTP1.

The CPU board (serial port connector (J5)) and the host PC should be connected by the serial cable.

Refer to "V850E2/ML4 CPU board R0K0F4022C000BR User's Manual" for more details about the CPU board jumper settings and connectors.

**Table 7.1 Jumper List**

Jumper	1-2 (default)	2-3 (used in this program)
JP1	VBUS	P2_3

An operation procedure with the VT100 compatible terminal emulator is described as follows. First of all, activate the terminal emulator and set for serial port connection. Select the number connected to the board for the serial port number of the terminal emulator. The setting values for serial ports are listed in Table 7.2.

Table 7.2 Serial Port Setting

Item	Setting Value
Bit/sec	9600bps
Data bit	8bit
Parity	None
Stop bit	1bit
Flow control	None

After the above setting is completed, turn on the through board and the board for this sample program.

When the board for this sample program is activated, the V850E2/ML4 transmits a message "Generate INTP1 interrupt for transition to flash programming event." to the host.

Then the V850E2/ML4 executes the program stored in the reprogram area, and flashes the LEDs on the board with the fixed period.

When the INTP1 switch (SW4) on the board is pushed in this condition, the V850E2/ML4 transmits a message "--> INTP1 detected!" to the host. When the INTP1 interrupt is generate, the V850E2/ML4 enters into flash reprogram processing, and erases the update area. After the erasing is completed, the V850E2/ML4 transmits a message "Send subroutine code to update program in Intel expanded Hex format." to the host, and enters into wait state for data reception from the host.

In case of transmitting a file with Intel expanded hex format as a program data from the host, the terminal emulator transmit function should be used. When choosing and transmitting the said file (such as v850e2ml4\_sample\_host\_send.hex), in this sample program, the received file is converted to program data and written to the flash memory.

After the writing is completed, the V850E2/ML4 transmits a message "Successfully Finish Writing Program Data. Please Reset." to the host, it enters into wait state for reset. Reset the board.

When restarting, the LEDs on the board flash with the different period from previous one. If the data reception/flash reprogram (update) prior to restart was failed to execute properly, the V850E2/ML4 finds a checksum error at the time of restarting by reset input. The V850E2/ML4 executes the program in the spare area.

## 8. Sample Code

Sample code can be downloaded from the Renesas Electronics website.

## 9. Reference Documents

### User's Manual: Hardware

V850E2/ML4 User's Manual: Hardware Rev.2.00 (R01UH0262EJ)

The latest version can be downloaded from the Renesas Electronics website.

### Technical Update/Technical News

The latest information can be downloaded from the Renesas Electronics website.

### User's Manual: Development Tools

CubeSuite+ V1.03.00 Integrated Development Environment User's Manual: Coding for CX compiler Rev.1.00 (R20UT2139EJ)

CubeSuite+ V1.03.00 Integrated Development Environment User's Manual: Build for CX compiler Rev.1.00 (R20UT2142EJ)

V850E2/ML4 CPU Board R0K0F4022C000BR User's Manual Rev.1.00 (R20UT0778EJ)

The latest version can be downloaded from the Renesas Electronics website.

### User's Manual: Software

V850E2/ML4 User's Manual: Architecture Rev.1.00 (R01US0001EJ)

The latest version can be downloaded from the Renesas Electronics website.

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<b>REVISION HISTORY</b>	V850E2/ML4 Application Note Updating Program Code Using Flash Self Programming with Asynchronous Serial Interface J (UARTJ)
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Rev.	Date	Description	
		Page	Summary
1.00	Mar. 18, 2013	—	First edition issued

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## General Precautions in the Handling of MPU/MCU Products

The following usage notes are applicable to all MPU/MCU products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

### 1. Handling of Unused Pins

Handle unused pins in accord with the directions given under Handling of Unused Pins in the manual.

- The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible. Unused pins should be handled as described under Handling of Unused Pins in the manual.

### 2. Processing at Power-on

The state of the product is undefined at the moment when power is supplied.

- The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the moment when power is supplied.

In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the moment when power is supplied until the reset process is completed.

In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the moment when power is supplied until the power reaches the level at which resetting has been specified.

### 3. Prohibition of Access to Reserved Addresses

Access to reserved addresses is prohibited.

- The reserved addresses are provided for the possible future expansion of functions. Do not access these addresses; the correct operation of LSI is not guaranteed if they are accessed.

### 4. Clock Signals

After applying a reset, only release the reset line after the operating clock signal has become stable.

When switching the clock signal during program execution, wait until the target clock signal has stabilized.

- When the clock signal is generated with an external resonator (or from an external oscillator) during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Moreover, when switching to a clock signal produced with an external resonator (or by an external oscillator) while program execution is in progress, wait until the target clock signal is stable.

### 5. Differences between Products

Before changing from one product to another, i.e. to one with a different part number, confirm that the change will not lead to problems.

- The characteristics of MPU/MCU in the same group but having different part numbers may differ because of the differences in internal memory capacity and layout pattern. When changing to products of different part numbers, implement a system-evaluation test for each of the products.

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